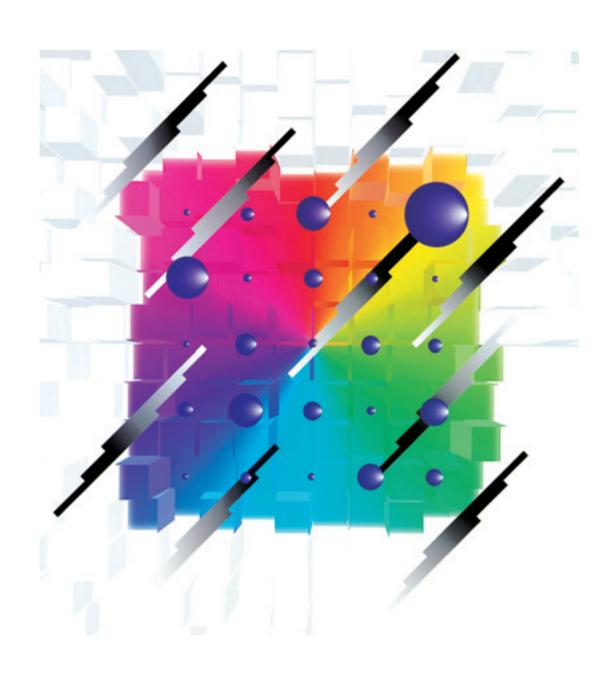


2018 CATALOG

Fixed Resistors



Panasonic

Fixed Resistors CONTENTS

Classifi	cation	Product Item	Part No.	Page
Safety Precau	tions (Commo	n precautions for Fixed Resistors)		2
	Chip	Thick Film Chip Resistors	ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T	3
	Resistors	Precision Thick Film Chip Resistors	ERJ XG, 1G, 1R, 2R, 3R, 6R, 3E, 6E, 8E, 14, 12, 1T	6
	High	Metal Film (Thin Film) Chip Resistors, High Reliability Type	ERA 1A, 2A, 3A, 6A, 8A	10
	Precision	High Precision Thick Film Chip Resistors	ERJ PB3, PB6	13
		Thick Film Chip Resistors / Low Resistance Type	ERJ 2LW, 3LW, 6LW, 2BW,3BW,6BW,8BW,6CW,8CW ERJ 2B, 3B, 6D, 6B, 8B, 14B, 3R, 6R, 8R, 14R, 12R,12Z, ERJ 1TR, L03, L06, L08, L14, L12, L1D, L1W	15
		Current Sensing Resistors, Metal Plate Type	ERJ MS4S, MS4H, MS6S, MB1S	20
	Current Sensing	Current Sensing Resistors, Metal Plate Type	ERJ M1WS, M1WT	24
	Sensing	Current Sensing Resistors, Metal Foil Type	ERJ MFBA	26
		High Power Chip Resistors / Wide Terminal Type	ERJ A1, B1, B2, B3	28
		Low TCR High Power Chip Resistors / Wide Terminal Type	ERJ D1, D2	32
	Small&High	Anti-Surge Thick Film Chip Resistors	ERJ PA2, P03, PA3, P06, P08, P14	34
Surface Mount Resistors	Power	Anti-Pulse Thick Film Chip Resistors	ERJ T06, T08, T14	37
	Anti-Sulfurated	Anti-Sulfurated Thick Film Chip Resistors	ERJ S02, S03, S06, S08, S14, S12, S1D, S1T ERJ U01, U02, U03, U06, U08, U14, U12, U1D, U1T ERJ U6S, U6Q	40
		Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type	ERJ UP6, UP8	43
		Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type	ERJ C1	46
		Chip Resistor Array	EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V	48
	Resistor Network/Array	Anti-Sulfurated Chip Resistor Array	EXB U14, U18, U24, U28, U2H, U34, U38	52
	inetwork/Array	Chip Resistor Networks	EXB D, E, A, Q	55
		Chip Attenuator	EXB 14AT, 24AT	57
		Packaging Methods (Taping)		59
	Common	Recommended Land Pattern		64
	specifications	Recommended Soldering Conditions		66
		Safety Precautions (Common precautions for	or Surface Mount Resistors)	67
Pow		Metal (Oxide) Film Resistors, Flame-Retardant	ERG 12S, 1S, 1F, 2S, 2F, 3S, 3F, 5S, 5F ERX 12S, 1S, 1F, 2S, 2F, 3S, 3F, 5S, 5F	68
Type Re (Leac		Anti-Pulse Power Resistors	ERG 12D, 1D, 2D, 3D	75
(2340	- ~/	Metal Film Resistors / Low Resistance Value	ERX 12L, 1L, 2L	77
Fusing R	esistors	Metal Film Fusing Resistors	ERQ 1Z, 2Z, 12Z, 14Z ERQ 1AB, 2AB, 12A, 14A	79
Fixed Resisto	rs Appendix			85

All products in this catalog comply with the RoHS Directive.

The RoHS Directive is "the Directive (2011/65/EU) on the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment" and its revisions.

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△Safety Precautions (Common precautions for Fixed Resistors)

- When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products.
- Install the following systems for a failsafe design to ensure safety if these products are to be used in equipment where a defect in these products may cause the loss of human life or other significant damage, such as damage to vehicles (automobile, train, vessel), traffic lights, medical equipment, aerospace equipment, electric heating appliances, combustion/gas equipment, rotating equipment, and disaster/crime prevention equipment.
- * Systems equipped with a protection circuit and a protection device
- * Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single fault

(1) Precautions for use

- These products are designed and manufactured for general and standard use in general electronic equipment (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment)
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
 - 1. In liquid, such as water, oil, chemicals, or organic solvent
 - 2. In direct sunlight, outdoors, or in dust
 - 3. In salty air or air with a high concentration of corrosive gas, such as Cl2, H2S, NH3, SO2, or NO2
 - 4. Electric Static Discharge (ESD) Environment
 - These components are sensitive to static electricity and can be damaged under static shock (ESD).
 - Please take measures to avoid any of these environments.
 - Smaller components are more sensitive to ESD environment.
 - 5. Electromagnetic Environment
 - Avoid any environment where strong electromagnetic waves exist.
 - 6. In an environment where these products cause dew condensation
 - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to leave water residues. Otherwise, the insulation performance may be deteriorated.

(2) Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- 1. In salty air or in air with a high concentration of corrosive gas, such as Cl2, H2S, NH3, SO2, or NO2
- 2. In direct sunlight

<Package markings>

Package markings include the product number, quantity, and country of origin. In principle, the country of origin should be indicated in English.

102



Thick Film Chip Resistors

Type: **ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T**

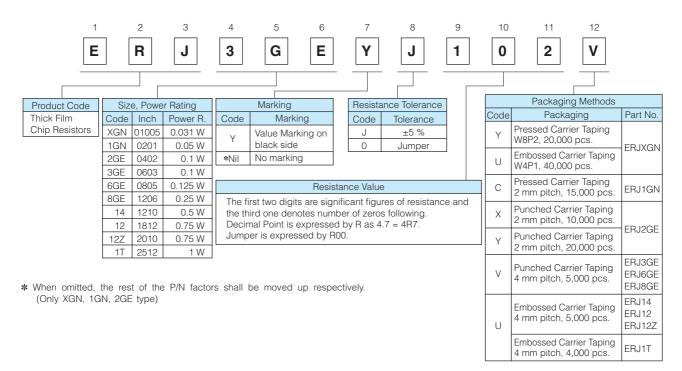


Features

- Small size and lightweight
- High reliability
 Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines
 Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standards
 IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified (Exemption ERJXG)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files

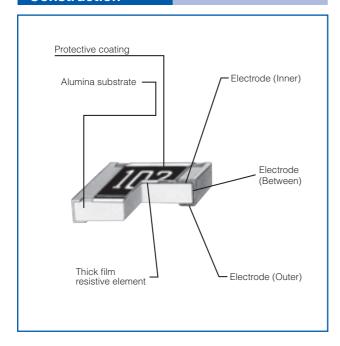
Explanation of Part Numbers

● ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T Type, ±5 %

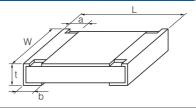


Thick Film Chip Resistors

Construction



Dimensions in mm (not to scale)



Part No.		Dim	ensions (r	mm)		Mass (Weight)
Tartino.	L	W	а	b	t	(g/1000 pcs.)
ERJXG	0.40 ^{±0.02}	0.20 ^{±0.02}	0.10 ^{±0.03}	0.10 ^{±0.03}	0.13 ^{±0.02}	0.04
ERJ1G	0.60 ^{±0.03}	0.30 ^{±0.03}	0.10 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.15
ERJ2G	1.00 ^{±0.05}	0.50 ^{±0.05}	0.20 ^{±0.10}	0.25 ^{±0.05}	0.35 ^{±0.05}	0.8
ERJ3G	1.60 ^{±0.15}	0.80+0.15	0.30 ^{±0.20}	0.30 ^{±0.15}	0.45 ^{±0.10}	2
ERJ6G	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4
ERJ8G	3.20+0.05	1.60+0.05	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10
ERJ14	3.20 ^{±0.20}	2.50 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16
ERJ12	4.50 ^{±0.20}	3.20 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	27
ERJ12Z	5.00 ^{±0.20}	2.50 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	27
ERJ1T	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	45

Ratings

[For Resistor]

[1 Of Ticolo								
Part No. (inch size)	Power Rating (3) at 70 °C (W)	Limiting Element Voltage (1) (V)	Maximum Overload Voltage (2)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1M (E24)	<10 Ω : -100 to +600 10 Ω to 100 Ω : ±300 100 Ω ≤ : ±200	-55 to +125	_
ERJ1G (0201)	0.05	25	50	±5	1 to 10M (E24)		-55 to +125	Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10M (E24)		-55 to +155	Grade 0
ERJ3G (0603)	0.1	75	150	±5	1 to 10M (E24)	<10 Ω: -100 to +600	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10M (E24)		-55 to +155	Grade 0
ERJ8G (1206)	0.25	200	400	±5	1 to 10M (E24)	10 Ω to 1M Ω : ±200	-55 to +155	Grade 0
ERJ14 (1210)	0.5	200	400	±5	1 to 10M (E24)		-55 to +155	Grade 0
ERJ12 (1812)	0.75	200	500	±5	1 to 10M (E24)	1M Ω <: -400 to +150	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10M (E24)		-55 to +155	Grade 0
ERJ1T (2512)	1	200	500	±5	1 to 1M (E24)		-55 to +155	Grade 0

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (3) Use it on the condition that the case temperature is below the upper category temperature.

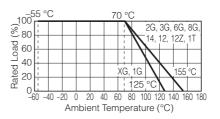
[For Jumper]

[i oi ouilibei]			
Part No.	Rated Current	Maximum Overload Current (1)	
(inch size)	(A)	(A)	
ERJXG (01005)	0.5	1	
ERJ1G (0201)	0.5	I	
ERJ2G (0402)	1	2	
ERJ3G (0603)	I		
ERJ6G (0805)			
ERJ8G (1206)			
ERJ14 (1210)	2	4	
ERJ12 (1812)	_	4	
ERJ12Z (2010)			
ERJ1T (2512)			

(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.





Thick Film Chip Resistors

Perfomance

Test Item	Performance	Requirements	Test Conditions
rest item	Resistor type	Jumper type	lest Conditions
Resistance	Within Specified Tolerance	50m Ω or less	20 °C
T. C. R.	Within Specified T. C. R.	50m Ω or less	+25 °C/+155 °C (ERJXG, ERJ1G : +25 °C/+125 °C)
Overload	±2%	50m Ω or less	Rated Voltage × 2.5, 5 s Jumper type: Max. Overload Current, 5 s
Resistance to Soldering Heat	±1%	50m Ω or less	270 °C, 10 s
Rapid Change of Temperature	±1%	50m Ω or less	-55 °C (30min.) / +155 °C (ERJXG, ERJ1G: +125 °C) (30min.), 100 cycles
High Temperature Exposure	±1%	50m Ω or less	+155 °C (ERJXG, ERJ1G : +125 °C) , 1000 h
Damp Heat, Steady State	±1%	50m Ω or less	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±3%	50m Ω or less	60 °C, 90% to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	50m Ω or less	70 °C, Rated Voltage(Jumper type: Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000 h

Precision Thick Film Chip Resistors

Precision Thick Film Chip Resistors

Type: ERJ XG, 1G ERJ 1R, 2R, 3R, 6R ERJ 3E, 6E, 8E, 14, 12, 1T



Features

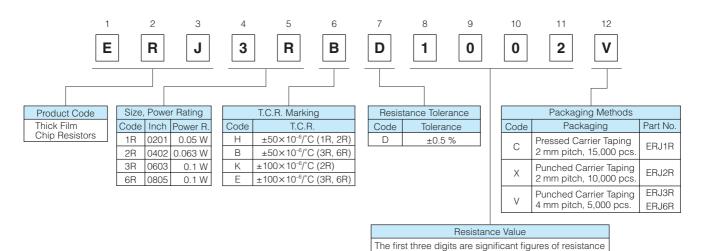
- Small size and lightweight
- High reliability

Metal glaze thick film resistive element and three layers of electrodes

- Compatible with placement machines Taping packaging available
- Suitable for both reflow and flow soldering
- Low Resistance Tolerance
 ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T Type: ±1 %
 ERJ1R, 2R, 3R, 6R Type: ±0.5 %
- Reference Standards IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified (Exemption ERJXG, ERJ1R)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

ERJ1R, 2R, 3R, 6R Type, ±0.5 %



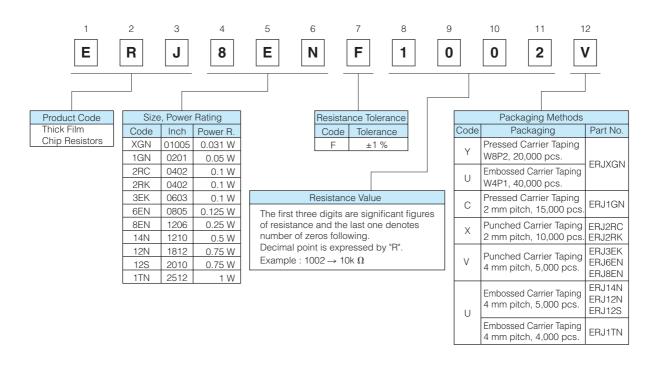
and the last one denotes number of zeros following.

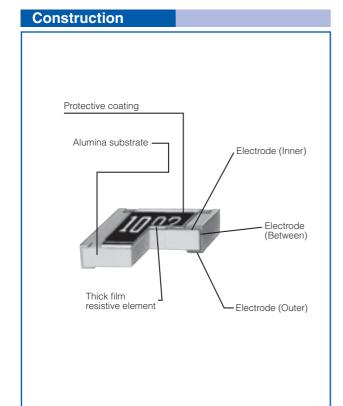
Example: $1002 \rightarrow 10k \Omega$

Panasonic

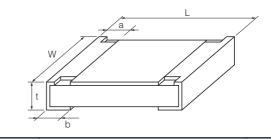
Precision Thick Film Chip Resistors

● ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN Type, ±1%





Dimensions in mm (not to scale)



Part No.		Dim	ensions (r	nm)		Mass (Weight)
rait No.	L	W	а	b	t	[g/1000 pcs.]
ERJXG	0.40 ^{±0.02}	0.20 ^{±0.02}	0.10 ^{±0.03}	0.10 ^{±0.03}	0.13 ^{±0.02}	0.04
ERJ1G, 1R	0.60 ^{±0.03}	0.30 ^{±0.03}	0.10 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.15
ERJ2R□	1.00 ^{±0.05}	0.50 ^{±0.05}	0.20 ^{±0.10}	0.25 ^{±0.05}	0.35 ^{±0.05}	0.8
ERJ3R□ ERJ3EK	1.60 ^{±0.15}	0.80 +0.15	0.30 ^{±0.20}	0.30 ^{±0.15}	0.45 ^{±0.10}	2
ERJ6R□ ERJ6EN	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4
ERJ8EN	$3.20^{+0.05}_{-0.20}$	1.60+0.05	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10
ERJ14N	3.20 ^{±0.20}	2.50 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16
ERJ12N	4.50 ^{±0.20}	3.20 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	27
ERJ12S	5.00 ^{±0.20}	2.50 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	27
ERJ1TN	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	45

Precision Thick Film Chip Resistors

Ratings

<±0.5 %>

Part No. (inch size)	Power Rating at 70 °C ⁽⁴⁾ (W)	Limiting Element Voltage (1) (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1k to 1M (E24, E96)	±50	-55 to +125	_
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100k (E24, E96)	±50	-55 to +155	Grade 0
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102k to 1M (E24, E96)	±100	-55 to +155	Grade 0
ERJ3RB (0603)	0.1	50	100	±0.5	100 to 100k (E24, E96)	±50	-55 to +155	Grade 0
ERJ3RE (0603)	0.1	50	100	±0.5	10 to 97.6 102k to 1M (E24, E96)	±100	-55 to +155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100k (E24, E96)	±50	-55 to +155	Grade 0
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102k to 1M (E24, E96)	±100	-55 to +155	Grade 0

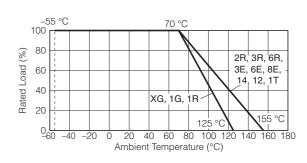
<±1 %>

Part No. (inch size)	Power Rating at 70 °C (4) (W)	Limiting Element Voltage (1) (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ⁽³⁾ (E24, E96)	<100 Ω : ±300 100 Ω ≤ : ±200	-55 to +125	_
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ⁽³⁾ (E24, E96)	±200	-55 to +125	Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76 (E24, E96)	-100 to +600	-55 to +155	Grade 0
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
ERJ1TN (2512)	1	200	500	±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (3) Please contact us when you need a type with a resistance of less than 10 Ω_{\cdot}
- (4) Use it on the condition that the case temperature is below the upper category temperature.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.





Precision Thick Film Chip Resistors

Perfomance

● ERJ1R, 2R, 3R, 6R Type, ±0.5%(D)

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.5, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30min.) / +155 °C (ERJ1R : +125 °C) (30min.), 100 cycles
High Temperature Exposure	±1%	+155 °C (ERJ1R : +125 °C) , 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±2% ERJ1R: ±3%	60 °C, 90% to 95 %RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±2% ERJ1R: ±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

● ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN Type, ±1%(F)

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C (ERJXG, ERJ1G : +25 °C/+125 °C)
Overload	±2%	Rated Voltage × 2.5, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30min.) / +155 °C (ERJXG, ERJ1G : +125 °C) (30min.), 100 cycles
High Temperature Exposure	±1%	+155 °C (ERJXG, ERJ1G : +125 °C) , 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±2% ERJXG, ERJ1G: ±3%	60 °C, 90% to 95 %RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±2% ERJXG, ERJ1G: ±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

102



Metal Film (Thin Film) Chip Resistors, High Reliability Type

Type: ERA 1A, 2A, 3A, 6A, 8A

Features

• High reliability Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range: -55 °C to +155 °C)

High accuracy Small resistance tolerance and Temperature Coefficient of Resistance

• High performance Low current noise, excellent linearity

• Reference Standard ······ IEC 60115-8, JIS C 5201-8, EIAJ RC-2133B

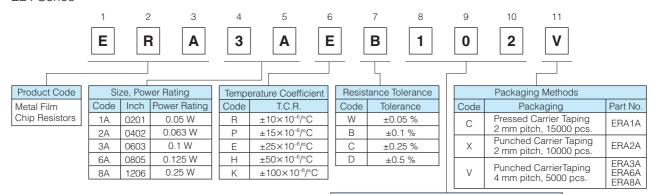
AEC-Q200 qualified

RoHS compliant

■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

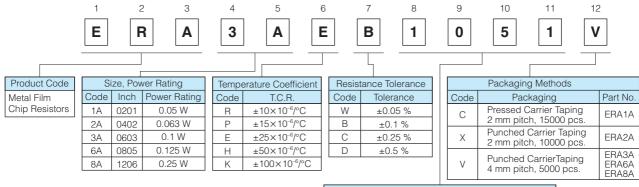
• E24 Series



Resistance Value

Consist of three figures for E24 series resistance value. The first two digits are significant figures of resistance and the third one denotes number of zeros following. (example) 102 : 1k $\boldsymbol{\Omega}$

E96 Series and other Resistance values



Resistance Value

Consist of four figures for E96 series resistance value. The first three digits are significant figures of resistance and the fourth one denotes number of zeros following. (example) 1051 : 1.05k Ω

note: Duplicated resistance values as E24 series part numbers shall follow E24 part numbers. (apply three digit resistance value)



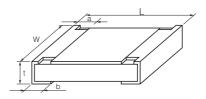
High reliability

metal film

Construction Protective coating Electrode (Inner) Alumina substrate Electrode (Between)

Electrode (Outer)

Dimensions in mm (not to scale)



Part No.		Dimensions (mm)						
(inch size)	L	W	а	b	t	[g/1000 pcs.]		
ERA1A (0201)	0.60 ^{±0.03}	0.30 ^{±0.03}	0.15 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.14		
ERA2A (0402)								
ERA3A (0603)	1.60 ^{±0.20}	0.80 ^{±0.20}	0.30 ^{±0.20}	$0.30^{\pm0.20}$	0.45 ^{±0.10}	2		
ERA6A (0805)						4		
ERA8A (1206)	3.20 ^{±0.20}	1.60 ± 8:95	0.50 ^{±0.25}	0.50 ^{±0.25}	0.60 ^{±0.10}	8		

Ratings

Part No. (inch size)	Power Rating at 85 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Part No. (detail)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /°C)	Resistance Range ⁽³⁾⁽⁴⁾ (Ω)	Category Temperature Range (°C)
				ERA1AEB	±0.1	±25	100 to 10k (E24, E96)	
ERA1A				ERA1AEC	±0.25		(== 1, == 3)	
(0201)	0.05	25	50	ERA1ARC	±0.25		100 to 10k (E24, E96)	
,				ERA1ARB	±0.1	±10	, , ,	
				ERA1ARW	±0.05	100	1k to 10k (E24, E96)	
				ERA2AKD	±0.5	±100	10 to 46.4 (E24, E96)	-
				ERA2AED	±0.5	05	47 to 400k (F04 F00)	
				ERA2AEC	±0.25	±25	47 to 100k (E24, E96)	
ERA2A	0.063	50	100	ERA2AEB	±0.1			_
(0402)				ERA2APC	±0.25	±15	200 to 47k (E24, E96)	
				ERA2APB	±0.1		, , ,	_
				ERA2ARC	±0.25	±10	200 to 47k (E24, E96)	
				ERA2ARB	±0.1			╛
				ERA3AHD	±0.5	±50	10 to 46.4 (E24, E96)	_
				ERA3AED	±0.5	0.5	47	
		75	150	ERA3AEC	±0.25	±25	47 to 330k (E24, E96)	
ERA3A				ERA3AEB	±0.1	±15		
(0603)	0.1			ERA3APC	±0.25		470 to 100k (E24, E96)	
				ERA3APB	±0.1		, , ,	_ _55 to +155
				ERA3ARC	±0.25		44 4 4001 (504 500)	
				ERA3ARB	±0.1		1k to 100k (E24, E96)	
				ERA3ARW	±0.05	50	10 1 10 1 (504 500)	_
				ERA6AHD	±0.5	±50	10 to 46.4 (E24, E96)	
				ERA6AED	±0.5	0.5	47	
				ERA6AEC	±0.25	±25	47 to 1M (E24, E96)	
ERA6A	0.405	100	000	ERA6AEB	±0.1			_
(0805)	0.125	100	200	ERA6APC	±0.25	±15	470 to 100k (E24, E96)	
				ERA6APB	±0.1		, , ,	_
				ERA6ARC	±0.25	10	41. t- 4001. (F04 F00)	
				ERA6ARB	±0.1	±10	1k to 100k (E24, E96)	
				ERA6ARW	±0.05	50	10 to 10 (F04 F00)	-
				ERA8AHD	±0.5	±50	10 to 46.4 (E24, E96)	_
				ERA8AED	±0.5	05	47 +- 414 /504 500)	
				ERA8AEC	±0.25	±25	47 to 1M (E24, E96)	
ERA8A	0.05	150	000	ERA8AEB	±0.1			-
(1206)	0.25	150	300	ERA8APC	±0.25	±15	470 to 100k (E24, E96)	
				ERA8APB	±0.1		, , ,	
				ERA8ARC	±0.25	10	41. t- 4001. (F04 F00)	
				ERA8ARB	±0.1	±10	1k to 100k (E24, E96)	
				ERA8ARW	±0.05			

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=VRated Power × Resistance Values, or Limiting Element Voltage listed above, whichever less.

(2) Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 × RCWV or max. Overload Voltage listed above whichever less.

(3) E192 series resistance values are also available. Please contact us for details.

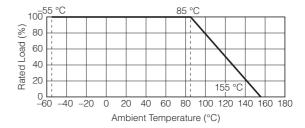
(4) Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)



Metal Film (Thin Film) Chip Resistors, High Reliability Type

Power Derating Curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



High Precision Thick Film Chip Resistors

I-

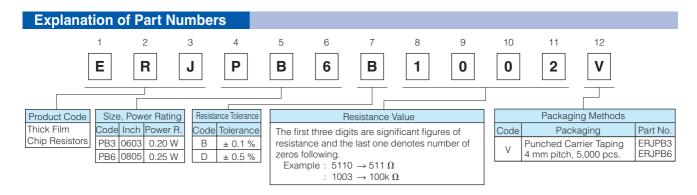
Type: ERJ PB3, PB6

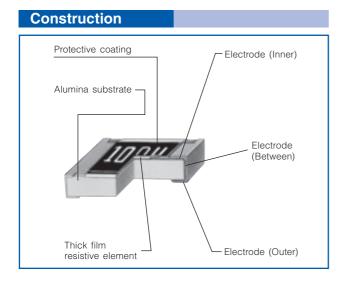
Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- ullet Guarantee the temperature coefficient of Resistance $\pm 50 \times 10^{-6}$ /°C in high resistance range up to 1M Ω
- Suitable for both reflow and flow soldering
- High power … 0.20 W: 0603 inch / 1608 mm size (ERJPB3)

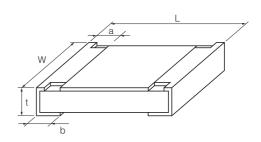
0.25 W: 0805 inch / 2012 mm size (ERJPB6)

- Reference Standards… IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files





Dimensions in mm (not to scale)



Part No.			Mass (Weight)			
(inch size)	L	W	а	b	t	[g/1000 pcs.]
ERJPB3 (0603)	1.60 ^{±0.15}	0.80+0.15	0.15+0.15	0.25 ^{±0.10}	0.45 ^{±0.10}	2
ERJPB6 (0805)	2.00 ^{±0.20}	1.25 ^{±0.10}	0.25 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4



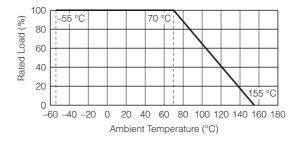
High Precision Thick Film Chip Resistors

Ratings							
Part No. (inch size)	Power Rating ⁽³⁾ at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100k (E24, E96)	±50	-55 to +155
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1M (E24, E96)	±50	-55 to +155

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=VPower Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less. (2) Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 × RCWV or max. Overload Voltage listed above whichever less.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



⁽³⁾ Use it on the condition that the case temperature is below 155 °C.

Thick Film Chip Resistors / Low Resistance Type

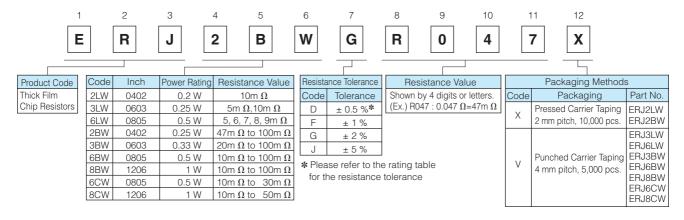
Type: ERJ 2LW, 3LW, 6LW 2BW, 3BW, 6BW, 8BW, 6CW, 8CW ERJ 2B, 3B, 6D, 6B, 8B, 14B, 3R, 6R, 8R, 14R, ... 12R, 12Z, 1TR ERJ L03, L06, L08, L14, L12. L1D. L1W

Features

- Current Sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising: ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR: ±75×10⁻⁶/°C (ERJ6CW, 8CW)
- Low Resistance Value : Thick film resistors available from 5m Ω (ERJ3LW, 6LW)
- Reference Standards: IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 qualified
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

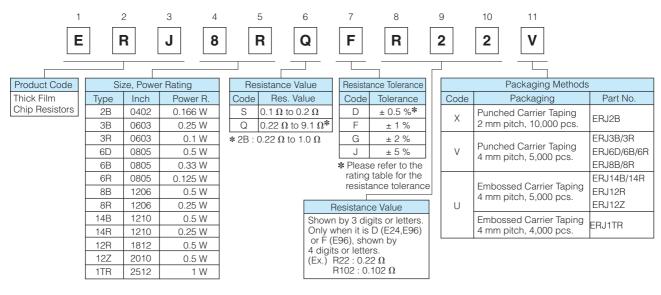
Explanation of Part Numbers

 ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW <High power (double-sided resistive elements structure) type>

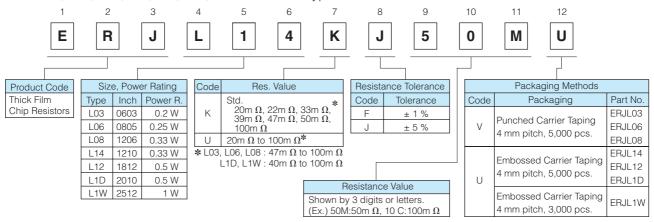


Panasonic Thick Film Chip Resistors / Low Resistance Type

ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR <High power type/Standard type>



● ERJL03, L06, L08, L14, L12, L1D, L1W <Low TCR type>



Ratings

<High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power Rating (2) at 70 °C (W)	Resistance Tolerance (%)	Resistance $^{(1)}$ Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJ2LW (0402)	0.2	±1, ±2, ±5	10m	0 to 500	-55 to +125	Grade 1
ERJ3LW (0603)	0.25	±1, ±2, ±5	5m	0 to 700	-55 to +125	Grade 1
ENJ3LW (0003)	0.23	±1, ±2, ±3	10m	0 to 300	-55 to +125	Grade i
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9m	0 to 300	-55 to +125	Grade 1
ERJ2BW (0402)	0.25	±1, ±2, ±5	47m to 100m (E24)	±300	-55 to +155	Grade 0
ERJ3BW (0603)	0.33	±1, ±2, ±5	20m to 100m (E24)	$\begin{array}{c} 20m \ \Omega \leq R < 39m \ \Omega : \pm 250 \\ 39m \ \Omega \leq R \leq 100m \ \Omega : \pm 150 \end{array}$	-55 to +155	Grade 0
ERJ6BW (0805)	0.5	±1, ±2, ±5	10m to 100m (E24)	$\begin{array}{c c} 10m \ \Omega \leq R < & 15m \ \Omega : \pm 300 \\ 15m \ \Omega \leq R \leq 100m \ \Omega : \pm 200 \end{array}$	-55 to +155	Grade 0
ERJ8BW (1206)	1	±1, ±2, ±5	10m to 100m (E24)	$\begin{array}{ll} 10m\;\Omega \leq R < & 20m\;\Omega: \pm 200 \\ 20m\;\Omega \leq R < & 47m\;\Omega: \pm 150 \\ 47m\;\Omega \leq R \leq 100m\;\Omega: \pm 100 \end{array}$	-55 to +155	Grade 0
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10m to 30m (E24)	±75	-55 to +125	Grade 1
ERJ8CW (1206)	1	±1, ±2, ±5	10m to 50m (E24)	±75	-55 to +125	Grade 1

⁽¹⁾ Please contact us when resistors of irregular series are needed.

(2) Use it on the condition that the case temperature is below the upper category temperature.

Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = V Power Rating × Resistance Values.

Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCW.

Panasonic

Thick Film Chip Resistors / Low Resistance Type

Ratings

<High power type>

Part No. (inch size)	Power Rating (2) at 70 °C (W)	Resistance (3) Tolerance (%)	Resistance $^{(1)}$ Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJ2BS (0402	0.166	±1, ±2, ±5	0.10 to 0.20 (E24)	±300	-55 to +155	Grade 0
ERJ2BQ (0402) 0.100	11, 12, 10	0.22 to 1.0 (E24)	±250	-55 to +155	Grade 0
ERJ3BS (0603)		0.10 to 0.20 (E24)	±300		Grade 0
ERJ3BQ (0603	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	±300	-55 to +155	
ENJ3DQ (0003	'		1.0 to 9.1 (E24)	±200		
ERJ6DS (0805	0.5	±0.5, ±1,	0.10 to 0.20 (E24, E96)	±150	-55 to +155	Grade 0
ERJ6DQ (0805) 0.5	±2, ±5	0.22 to 9.1 (E24, E96)	±100		
ERJ6BS (0805)		0.10 to 0.20 (E24)	±250		
ERJ6BQ (0805	0.33	±1, ±2, ±5	0.22 to 0.91 (E24)	±230	-55 to +155	Grade 0
EU1000 (0000)		1.0 to 9.1 (E24)	±200		
ERJ8BS (1206)		0.10 to 0.20 (E24)	±250		
ERJ8BQ (1206	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	±230	-55 to +155	Grade 0
ENJOBQ (1200	'		1.0 to 9.1 (E24)	±200		
ERJ14BS (1210			0.10 to 0.20 (E24)	±200		Grade 0
ERJ14BQ (1210	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	±200	-55 to +155	
ENJ 14DQ (1210	/		1.0 to 9.1 (E24)	±100		

- (1) Please contact us when resistors of irregular series are needed.
- (2) Use it on the condition that the case temperature is below the upper category temperature.
- (3) E96 series also have ±0.5 %, ±1 % line-up.
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating}} \times \text{Resistance Values}$.
- · Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

<Standard type>

Part I (inch		Power Rating (2) at 70 °C (W)	Resistance Tolerance (%)	Resistance $^{(1)}$ Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade	
ERJ3RS	(0603)			0.10 to 0.20 (E24)	±300			
ERJ3RQ	(0603)	0.1	±1, ±2, ±5	0.22 to 0.91 (E24)		-55 to +155	Grade 0	
	,			1.0 to 9.1 (E24)	±200			
ERJ6RS	(0805)			0.10 to 0.20 (E24)	±250			
ERJ6RQ	(0805)	0.125	±1, ±2, ±5	0.22 to 0.91 (E24)		-55 to +155	Grade 0	
	(0000)			1.0 to 9.1 (E24)	±200			
ERJ8RS	(1206)			0.10 to 0.20 (E24)	±250			
ERJ8RQ	(1206)	0.25	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)		-55 to +155	Grade 0
				1.0 to 9.1 (E24)	±200			
ERJ14RS	(1210)			0.10 to 0.20 (E24)	±200			
ERJ14RQ	(1210)	0.25	0.25 $\pm 1, \pm 2, \pm 5$	0.22 to 0.91 (E24)	±200	-55 to +155	Grade 0	
	(1210)			1.0 to 9.1 (E24)	±100			
ERJ12RS	(1812)			0.10 to 0.20 (E24)	±200			
ERJ12RQ	(1010)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	±200	-55 to +155	Grade 0	
LHJIZHG	(1012)			1.0 to 9.1 (E24)	±100			
ERJ12ZS	(2010)			0.10 to 0.20 (E24)	±200			
ERJ12ZQ	(2010)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	±200	-55 to +155	Grade 0	
LNJ 12ZQ	(2010)			1.0 to 9.1 (E24)	±100			
ERJ1TRS	(2512)			0.10 to 0.20 (E24)	±200			
ED HTDC	(2512)	1	±1, ±2, ±5	0.22 to 0.91 (E24)	±200	-55 to +155	Grade 0	
ERJ1TRQ (2512)			, , -	1.0 to 9.1 (E24)	±100			

⁽¹⁾ Please contact us when resistors of irregular series are needed.

(2) Use it on the condition that the case temperature is below the upper category temperature.

Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Values}}$.

Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

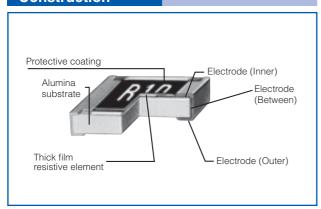
Panasonic Thick Film Chip Resistors / Low Resistance Type

<Low TCR type>

Part (inch	INO.	Power Rating (2) at 70 °C (W)	Resistance Tolerance (%)	Resistance $^{(1)}$ Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJL03	(0603)	0.2	±1, ±5	47m to 100m	±200	-55 to +125	Grade 1
ERJL06	(0805)	0.25	±1, ±5	47m to 100m	±100	-55 to +125	Grade 1
ERJL08	(1206)	0.33	±1, ±5	47m to 100m	±100	-55 to +125	Grade 1
ERJL14	(1210)	0.33	±1, ±5	20m to 100m		-55 to +125	Grade 1
ERJL12	(1812)	0.5	±1, ±5	20m to 100m	$R < 47m \Omega : \pm 300$	-55 to +125	Grade 1
ERJL1D	(2010)	0.5	±1, ±5	40m to 100m	$R \ge 47 \text{m} \ \Omega : \pm 100$	-55 to +125	Grade 1
ERJL1W	(2512)	1	±1, ±5	40m to 100m		-55 to +125	Grade 1

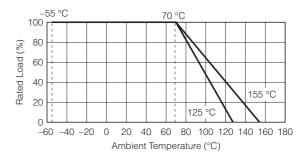
- (1) Standard R.V.: 20m Ω , 22m Ω , 33m Ω , 39m Ω , 47m Ω , 50m Ω , 100m Ω , Custom R.V.: Each 1m Ω within upper range. (2) Use it on the condition that the case temperature is below the upper category temperature.
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Values}}$.
- Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

Construction

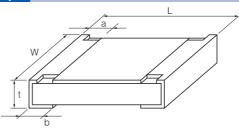


Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



Dimensions in mm (not to scale)



Part No.		Dime	ensions (mm)		Mass(Weight)
rait No.	L	W	а	b	t	[g/1000 pcs.]
ERJ2LW	1.00 ^{±0.10}	0.50+0.10	0.25 ^{±0.10}	0.25 ^{±0.10}	0.40 ^{±0.05}	0.8
ERJ2BW	1.00 ^{±0.10}	0.50+0.10	0.24 ^{±0.10}	0.24 ^{±0.10}	0.35 ^{±0.05}	0.8
ERJ2BS	1.00 ^{±0.10}	0.50+0.10	0.20 ^{±0.10}	0.27 ^{±0.10}	0.35 ^{±0.05}	0.8
ERJ2BQ	1.00	0.30-0.05 0.20 0.21	0.27	0.33	0.8	
ERJ3LW (5m Ω)	1.60 ^{±0.15}	0.80 ^{±0.15}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.55 ^{±0.10}	3
ERJ3LW (10m Ω) ERJ3BW	1.60 ^{±0.15}	0.80 ^{±0.15}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.55 ^{±0.10}	3
ERJ3R						
ERJ3B	1.60 ^{±0.15}	0.80 + 8:15	0.30 ^{±0.20}	0.30 ^{±0.15}	0.45 ^{±0.10}	2
ERJL03						
ERJ6LW	2.00 ^{±0.20}	1.25 ^{±0.20}	0.63 ^{±0.20}	0.63 ^{±0.20}	0.70 ^{±0.10}	6
ERJ6BW	2.00 ^{±0.20}	1.25 ^{±0.20}	0.55 ^{±0.20}	0.55 ^{±0.20}	0.65 ^{±0.10}	6
ERJ6CW (10 to 13m Ω)	2.05 ^{±0.20}	1.30 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.65 ^{±0.10}	6
ERJ6CW (15 to 30m Ω)	2.05	1.30	0.45 ^{±0.20}	0.45 ^{±0.20}	0.65	6
ERJ6D	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.55 ^{±0.25}	0.60 ^{±0.10}	5
ERJ6R						
ERJ6B	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	5
ERJL06						

Part No.		Mass(Weight)					
Tait No.	L	W	а	b	t	[g/1000 pcs.]	
ERJ8BW	3.20 ^{±0.20}	1.60 ^{±0.20}	1.00 ^{±0.20}	1.00 ^{±0.20}	0.65 ^{±0.10}	13	
ERJ8CW (10 to 16m Ω)	3.20 ^{±0.20}	1.60 ^{±0.20}	1.10 ^{±0.20}	1.10 ^{±0.20}	0.65 ^{±0.10}	13	
ERJ8CW (18 to 50m Ω)	3.20 ^{±0.20}	1.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.65 ^{±0.10}	13	
ERJ8R							
ERJ8B	3.20+0.05	1.60-0.15	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10	
ERJL08							
ERJ14R							
ERJ14B	3.20 ^{±0.20}	2.50 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16	
ERJL14							
ERJ12R	4.50 ^{±0.20}	3.20 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	27	
ERJL12	4.50	3.20	0.30	0.30	0.00	21	
ERJ12Z ERJL1D	5.00 ^{±0.20}	2.50 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	27	
ERJ1TR	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	45	
ERJL1W	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	1.30 ^{±0.20}	1.10 ^{±0.10}	79	

Panasonic Thick Film Chip Resistors / Low Resistance Type

Performance

● ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW <High power (double-sided resistive elements structure) type>

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.0, 5 s ERJ6LW : × 1.77, 5 s ERJ8BW (R > 0.05 Ω) : × 1.77, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1% ERJ2LW : ±2%	-55 °C (30 min.) / +155 °C (ERJ * LW, ERJ * CW : +125 °C) (30 min.), 100 cycles
High Temperature Exposure	±1%	+155 °C (ERJ*LW, ERJ*CW : +125 °C), 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR <High power type/Standard type>

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.5 (ERJ6D: × 1.77), 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

● ERJL03, L06, L08, L14, L12, L1D, L1W <Low TCR type>

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.5, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles
High Temperature Exposure	±1%	+125 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

Current Sensing Resistors, Metal Plate Type

Type: ERJ MS4, MS6, MB1

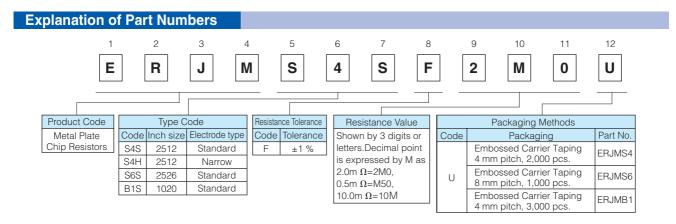


Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 qualified
- RoHS compliant
- ISO9001, ISO/TS16949 certified

■ As for Packaging Methods, Soldering Conditions and Safety Precautions,

Please see Data Files



Ratings						
Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range $(m\Omega)$	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	Terminal temp. upper limit (°C)
ERJMS4S (2512)	3	1, 2, 3, 4	F:±1	±75	-65 to +170	130
ERJMS4H	3	5, 6	F:±1	±75	-65 to +170	130
(2512)	2	7, 8, 9, 10	F:±1	±75	-65 to +170	100
ERJMS6S (2526)	5	0.5, 1, 2	F:±1	±75	-65 to +170	130
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F:±1	±75	-65 to +170	130

^{*} Please contact us when resistors of irregular series are needed.

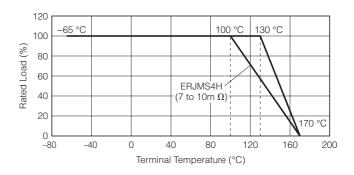
Power Derating Curve

If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.

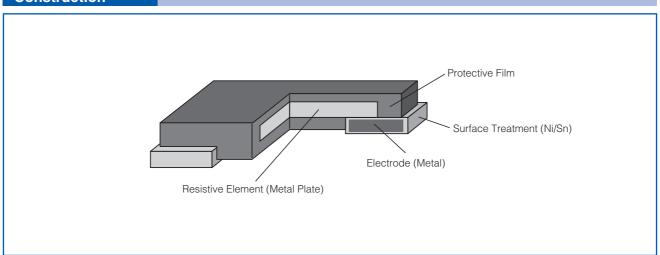


In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

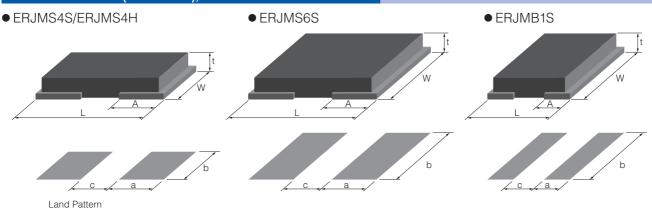
- Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions.



Construction

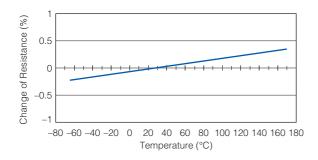


Dimensions in mm (not to scale), Recommended Land Pattern

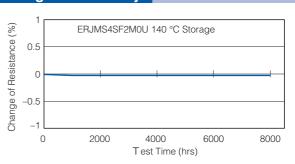


Part No.		Dimensi	on (mm)		Recommended Land Pattern (mm)			Mass (Weight)
(inch size)	L	W	А	t	а	b	С	(g/1000 pcs.)
ERJMS4S (2512)	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H (2512)	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMS6S (2526)	6.40±0.25	6.80±0.25	2.20±0.25	1.20±0.15	2.7	7.0	2.0	260
ERJMB1S (1020)	2.55±0.25	5.00±0.25	0.68+0.15	0.90±0.15	1.15	5.5	1.1	40

Typical Temperature dependence of electrical resistance



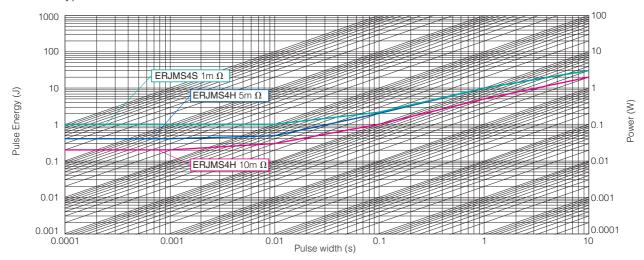
Long-term stability



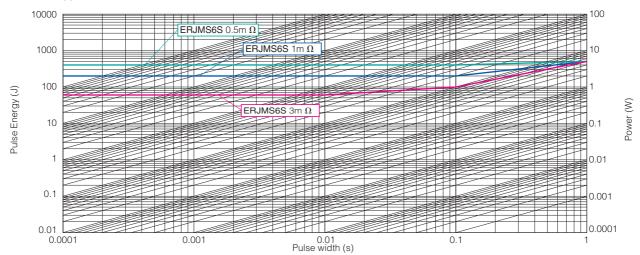
Maximum pulse energy respectively pulse power for continuous operation

Referance Data Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square Change of Resistance=±1 %

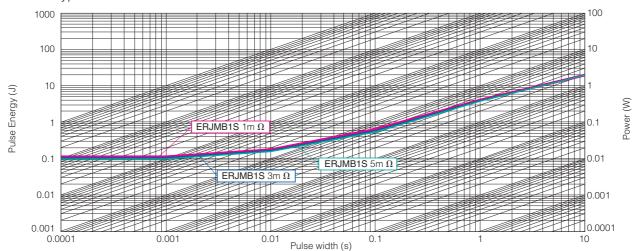
ERJMS4 type



ERJMS6 type



● ERJMB1 type



Performance (AEC-Q200)

● ERJMS4, ERJMS6 type

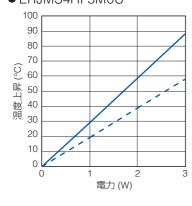
Test Item	Test Condition	Specification	Typical value
Thermal Shock	–55 °C/155 °C, 1000cycles	±1 %	0.20 %
Overload	3 × Rated Power, 5 sec	±0.5 %	0.10 %
Solderability	245 °C, 3 sec	> 95% coverage	> 95% coverage
Resistance to Solvents	MIL-STD-202 method 215, 2.1a, 2.1d	No damage	No damage
Low Temperature Storage and Operation	−65 °C, 24 h	±0.5 %	0.03 %
Resistance to Soldering Heat	MIL-STD-202 method 210 (260 °C, 10s)	±0.5 %	0.10 %
Moisture Resistance	MIL-STD-202 method 106	±0.5 %	0.10 %
Shock	MIL-STD-202 method 213-A	±0.5 %	0.10 %
Vibration, High Frequency	10 to 2000 (Hz)	±0.5 %	0.05 %
Life	70 °C, Rated Power, 2000 h	±1 %	0.30 %
Storage Life at Elevated Temperature	170 °C, 2000 h	±1 %	0.30 %
High Temperature Characteristics	140 °C, 2000 h	±0.5 %	0.05 %
Frequency Characteristics	Inductance	< 5 nH	< 2 nH

● ERJMB1 type

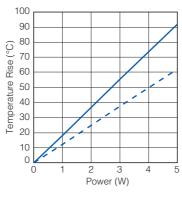
Test Item	Test Condition	Specification	Typical value
Thermal Shock	–55 °C/155 °C, 1000cycles	±1 %	0.30 %
Overload	2.5 × Rated Power, 5 sec	±1 %	0.30 %
Solderability	245 °C, 3 sec	> 95% coverage	> 95% coverage
Resistance to Solvents	MIL-STD-202 method 215, 2.1a, 2.1d	No damage	No damage
Low Temperature Storage and Operation	−65 °C, 24 h	±0.5 %	0.03 %
Resistance to Soldering Heat	MIL-STD-202 method 210 (260 °C, 10s)	±0.5 %	0.10 %
Moisture Resistance	MIL-STD-202 method 106	±0.5 %	0.10 %
Shock	MIL-STD-202 method 213-A	±0.5 %	0.10 %
Vibration, High Frequency	10 to 2000 (Hz)	±0.5 %	0.05 %
Life	70 °C, Rated Power, 2000 h	±1 %	0.30 %
Storage Life at Elevated Temperature	170 °C, 2000 h	±1 %	0.30 %
High Temperature Characteristics	140 °C, 2000 h	±0.5 %	0.05 %
Frequency Characteristics	Inductance	< 5 nH	< 2 nH

Temperature Rise

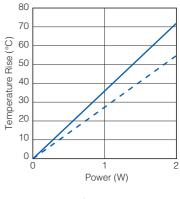
• ERJMS4HF5M0U



● ERJMS6SF2M0U



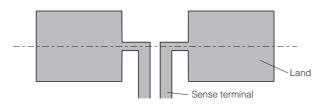
ERJMB1SF3M0U





Resistor 1 2 Soldering PWB

Sense terminal-Layout



Current Sensing Resistors, Metal Plate Type

Type: ERJM1W



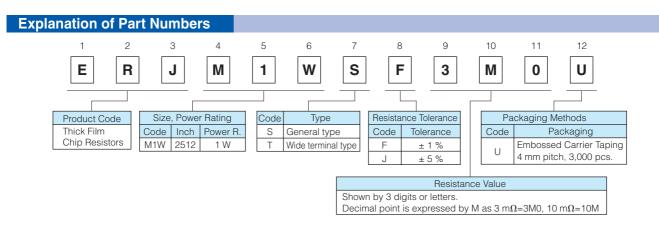


Features

- Low resistance values and high precision (1 m Ω to 20 m Ω)
- Stable resistance not influenced by measurement position
- High heat emission
- Low profile, strong body
- Inductance less than 1.0 nH for the metal plate structure
- RoHS compliant

■ As for Packaging Methods, Soldering Conditions and Safety Precautions,

Please see Data Files

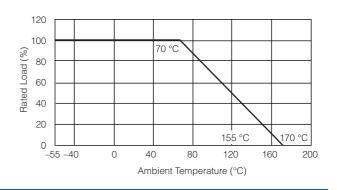


Ratings						
Part No. (inch size)	Power Rating at 70 °C (W)	Standard Resistance (m Ω)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	Circuit board of use
ERJM1WS		3, 4		±350		You should use the
(2512)	4	5, 6, 10, 15, 20	F: ±1, J: ±5	±100	_55 to +170	aluminum substrate
ERJM1WT	'	1, 1.5	Γ. ±1, J. ±3	350±100	-55 (0 + 170	when the added
(2512)		2, 3, 4		100±50		wattage exceeds 0.5 W.

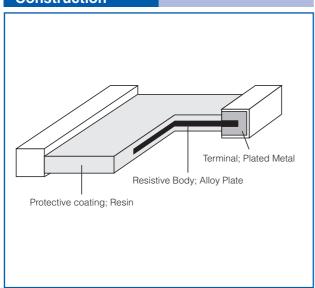
^{*} Please contact the factory for other values and the range

Power Derating Curve

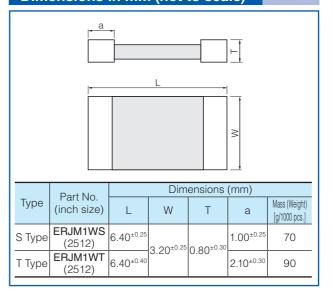
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction

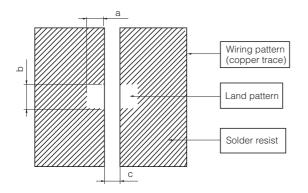


Dimensions in mm (not to scale)



Recommended Land Pattern

An example of a land pattern



Part No.	Dimensions (mm)				
rait No.	а	b	С		
ERJM1WS	2.1	3.4	4.2		
ERJM1WT	3.1	3.4	2.2		

Current Sensing Resistors, Metal Foil Type



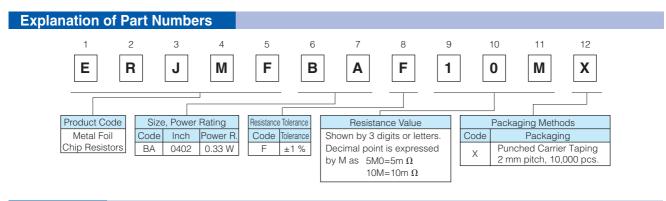
Type: ERJ MFBA

Features

- Suitable for current sensing for smartphones and other small devices
- Unique metal foil process achieved high power and low temperature coefficient
- RoHS compliant
- ISO9001 certified

■ As for Packaging Methods, Soldering Conditions and Safety Precautions,

Please see Data Files



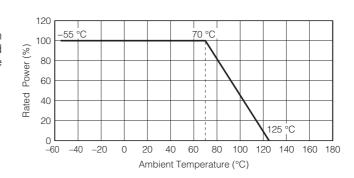
R	_	71		
т	r. I		·	-

Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range* $(m\Omega)$	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)
ERJMFBA (0402)	0.33	5, 10, 20	F: ±1	±150	-55 to +125

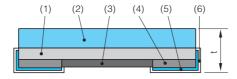
^{*} Use it on the condition that the case temperature is below 125 °C.

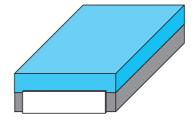
Power Derating Curve

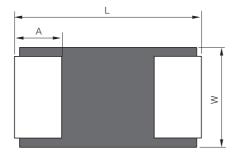
If the ambient temperature of the resistor is more than ambient temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.



Construction, Dimensions in mm (not to scale)



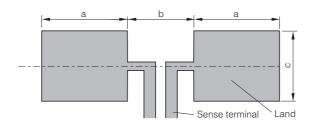




	Name
(1)	Resistive element
(2)	Base material
(3)	Protective Resin
(4)	Electrode (Inner)
(5)	Electrode (Between)
(6)	Electrode (Outer)

Part No.	Dimension (mm)					
Part No.	L	W	А	t	(g/1000 pcs.)	
ERJMFBA	1.00±0.10	0.55±0.10	0.25±0.10	0.30±0.10	0.73	

Recommended Land Pattern, Sense terminal-Layout



Part No.	Recommended Land Pattern (mm)				
Part No.	а	b	С		
ERJMFBA	0.40	0.50	0.50		

Pertorn	nance

Test Item	Test Condition	Specification	Typical value
Thermal Shock	–55 °C/125 °C, 5 cycles	±2 %	0.20 %
Overload	3 × Rated Power, 5 sec	±2 %	0.20 %
Solderability	245 °C, 3 sec	> 95% coverage	> 95% coverage
Resistance to Solvents	MIL-STD-202 method 215, 2.1a, 2.1d	No damage	No damage
Low Temperature Storage and Operation	−65 °C, 24 h	±1 %	0.10 %
Resistance to Soldering Heat	MIL-STD-202 method 210 (260 °C, 10 s)	±1 %	0.10 %
Moisture Resistance	MIL-STD-202 method 106	±1 %	0.10 %
Shock	MIL-STD-202 method 213-A	±1 %	0.10 %
Vibration, High Frequency	10 to 2000 (Hz)	±1 %	0.10 %
Life	70 °C, Rated Power, 1000 h	±3 %	0.30 %
Storage Life at Elevated Temperature	125 °C, 1000 h	±1 %	0.10 %
Frequency Characteristics	Inductance	< 5 nH	< 2 nH

High Power Chip Resistors / Wide Terminal Type

HIO

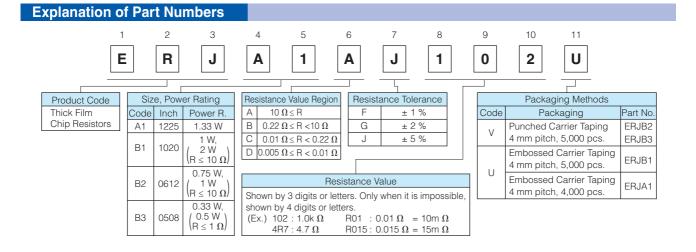
Type: ERJ A1, B1, B2, B3

Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 qualified
- RoHS compliant

Recommended Applications

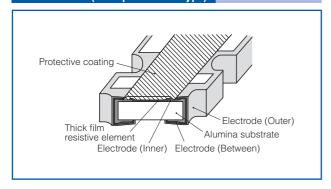
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files



Ratin	gs							
Part No. (inch size)	Power Rating ⁽³⁾ at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJA1				±1	100m to 10k (E24)	±100		
(1225)	1.33	200	400	±2, ±5	10m to 10k (E24)	$\begin{array}{c} \text{R}\!<\!100\text{m}\Omega:\pm350\\ \text{100m}\Omega\leq\text{R} \qquad :\pm200 \end{array}$	-55 to +155	Grade 0
ERJB1 (1020)	1 2(R ≤ 10 Ω)	200	400	±1	10m to 10k (E24)	$\begin{array}{c} R < 22m\Omega : \pm 350 \\ 22m\Omega \le R < 47m\Omega : \pm 200 \\ 47m\Omega \le R < 100m\Omega : \pm 150 \\ 100m\Omega \le R : \pm 100 \\ \end{array}$	-55 to +155	Grade 0
	_(,			±2, ±5	10m to 10k (E24)	$\begin{array}{ccc} & R < 22m\Omega : \pm 350 \\ 22m\Omega \le R & : \pm 200 \end{array}$		
ERJB2	0.75	200		±1	10m to 1M (E24)	$\begin{array}{c} {\sf R} < 22m\Omega : 0\ to\ +300 \\ 22m\Omega \le {\sf R} < 47m\Omega : 0\ to\ +200 \\ 47m\Omega \le {\sf R} < 100m\Omega : 0\ to\ +150 \\ 100m\Omega \le {\sf R} < 220m\Omega : 0\ to\ +100 \\ 220m\Omega \le {\sf R} \qquad : \pm 100 \end{array}$	-55 to +155	
(0612)	$1(R \le 10 \Omega)$	200	400	±2	10m to 1M (E24)	R< 22m Ω : 0 to +300	-55 10 + 155	Grade 0
				±5	5m, 6m, 7m, 8m, 9m, 10m to 1M (E24)	$\begin{array}{c} 22m\Omega \leq R < 47m\Omega : 0 \text{ to } +200 \\ 47m\Omega \leq R < 100m\Omega : 0 \text{ to } +150 \\ 100m\Omega \leq R < 220m\Omega : 0 \text{ to } +200 \\ 220m\Omega \leq R \qquad : \pm 200 \\ \end{array}$		
ERJB3	0.33	150	200	±1	20m to 10 (E24)	$\begin{array}{c} R<\ 47m\ \Omega\ :0\ to\ +300\\ 47m\ \Omega\ \le R< & 1\ \Omega\ :0\ to\ +200\\ 1\ \Omega\ \le R & :\ \pm 100 \end{array}$	-55 to +155	Grade 0
(0508)	$0.5(R \le 1 \Omega)$		200	±2, ±5	20m to 10 (E24)	$ \begin{array}{c c} & R < 47m \ \Omega : 0 \ to \ +300 \\ 47m \ \Omega \le R < & 1 \ \Omega : 0 \ to \ +200 \\ 1 \ \Omega \le R & : \pm 200 \end{array} $		314400

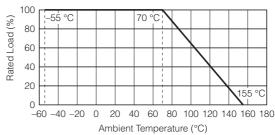
- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating} \times \text{Resistance Values}}$, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) x RCWV or Maximum Overload Voltage listed above, whichever less.
- (3) Use it on the condition that the case temperature is below the upper category temperature.

Construction (Example: ERJA1 type)



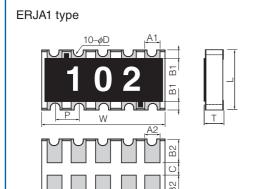
Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



Panasonic High Power Chip Resistors / Wide Terminal Type

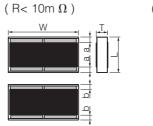
Dimensions in mm (not to scale)

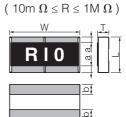


Mass (Weight) [1000 pcs.]: 40 g

Dimensions	L	W	Т	A ₁	B ₁
(mm)	3.20±0.20	6.40±0.20	0.55±0.10	0.70 ± 0.20	0.45±0.20
Dimensions	A ₂	B ₂	Р	ϕ D	С
(mm)	0.70±0.20	1.25±0.15	1.27±0.10	$0.30^{+0.10}_{-0.20}$	0.4 min.

ERJB2 type

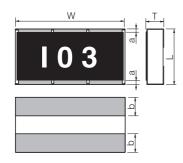




Mass (Weight) [1000 pcs.] : 11 g

Dimensions (mm)	L	W	Т	а	b
$5\text{m }\Omega \leq \text{R}{<}10\text{m }\Omega$			0.65±0.15	0.30±0.20	0.30±0.20
$10m \Omega \le R < 220m \Omega$ $220m \Omega \le R \le 1M \Omega$	1.60±0.15	3.20±0.20	0 55 , 0 15	0.30±0.20	0 50 10 20
220m $Ω$ ≤R≤1M $Ω$			0.00±0.10	0.25±0.20	0.50±0.20

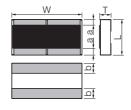
ERJB1 type



Mass (Weight) [1000 pcs.]: 27 g

Dimensions	L	W	Т	а	b
(mm)	2.50±0.20	5.00±0.20	0.55±0.20	0.25±0.20	0.90±0.20

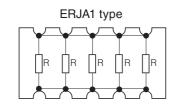
ERJB3 type



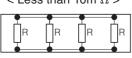
Mass (Weight) [1000 pcs.]: 4.8 g

Dimensions	L	W	Т	а	b
(mm)	1.25±0.10	2.00±0.15	0.50±0.10	0.25±0.20	0.40±0.20

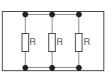
Circuit Configuration



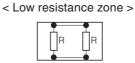
< Less than 10m $\Omega>$



ERJB1 type



ERJB2 type



ERJB3 type



< High resistance zone >



Panasonic High Power Chip Resistors / Wide Terminal Type

Perfomance		
Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	$\begin{array}{lll} \text{ERJA1, ERJB1 (R > 10), ERJB3 (R > 1)} & : \text{Rated Voltage} \times 2.5, 5 \text{ s} \\ \text{ERJB2 (R > 10)} & : \text{Rated Voltage} \times 2.2, 5 \text{ s} \\ \text{ERJB1 (R \leq 10), ERJB2 (R \leq 10), ERJB3 (R \leq 1)} : \text{Rated Voltage} \times 2.0, 5 \text{ s} \\ \end{array}$
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±2%	55 °C (30min.) / +125 °C (30min.), 1000 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95 %RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

Low TCR High Power Chip Resistors / **Wide Terminal Type**

.010

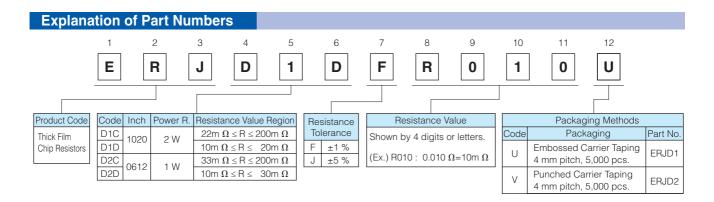
Type: ERJ D1, D2

Features

- Achieved High power and low TCR (±100×10⁻⁶/°C) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 qualified
- RoHS compliant

Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files



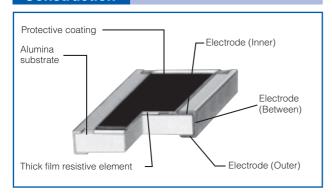
Ratings

Part No. (inch size)	Power Rating ⁽²⁾ at 70 °C (W)	Resistance Tolerance (%)	Resistance Range $^{^{(1)}}$ (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJD1 (1020)	2	±1, ±5	10m to 200m (E24)	±100	-55 to +155	Grade 0
ERJD2 (0612)	1	±1, ±5	10m to 200m (E24)	±100	-55 to +155	Grade 0

- (1) Please contact us when resistors of irregular series are needed.
- (2) Use it on the condition that the case temperature is below the upper category temperature.
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Values}}$.
- · Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

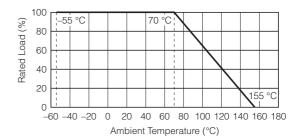
Panasonic Low TCR High Power Chip Resistors / Wide Terminal Type

Construction

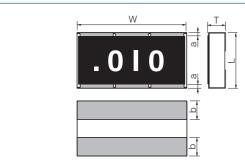


Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

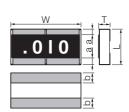


Dimensions in mm (not to scale)



Mass (Weight) [1000 pcs.] : 27 g

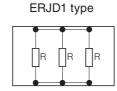
Part No.		Dim	ensions (mm)	
rait NO.	L	W	Т	a	b
ERJD1	2.50±0.20	5.00±0.20	0.60±0.20	0.30±0.20	0.90±0.20



Mass (Weight) [1000 pcs.]: 11 g

Part No.		Dimensions (mm)						
rait No.	L	W	Т	(mm) a 0.30±0.20 0.50	b			
ERJD2	1.60±0.15	3.20±0.20	0.65±0.15	0.30±0.20	0.50±0.20			

Circuit Configuration



ERJD2 type



Perfomance

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.0, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±2%	55 °C (30min.) / +125 °C (30min.), 1000 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95 %RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h



Anti-Surge Thick Film Chip Resistors

Type: ERJ PA2, P03, PA3, P06, P08, P14



Features

- ESD surge characteristics superior to standard metal film resistors
- High reliability

Metal glaze thick film resistive element and three layers of electrodes

- Suitable for both reflow and flow soldering
- High power ··· 0.20 W: 0402 inch / 1005 mm size (ERJPA2), 0603 inch / 1608 mm size (ERJP03)

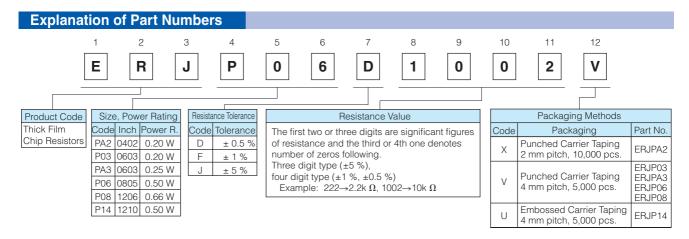
0.25 W: 0603 inch / 1608 mm size (ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

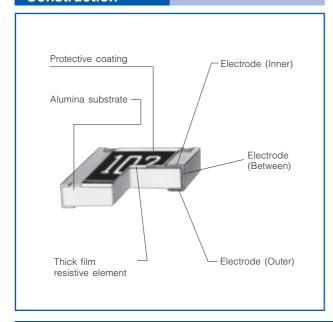
0.66 W: 1206 inch / 3216 mm size (ERJP08)

- Reference Standards… IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified
- RoHS compliant

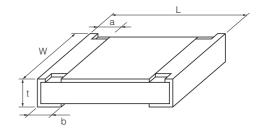
■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files



Construction



Dimensions in mm (not to scale)



Part No.		Dim	ensions (r	nm)		Mass (Weight)
rait No.	L	W	а	b	t	[g/1000 pcs.]
ERJPA2	1.00 ^{±0.05}	0.50 ^{±0.05}	0.20 ^{±0.15}	0.25 ^{±0.05}	0.35 ^{±0.05}	0.8
ERJP03	1.60 ^{±0.15}	0.80+0.15	0.15+0.15	0.30 ^{±0.15}	0.45 ^{±0.10}	2
ERJPA3	1.60 ^{±0.15}	0.80+0.15	0.15+0.15	0.25 ^{±0.10}	0.45 ^{±0.10}	2
ERJP06	2.00 ^{±0.20}	1.25 ^{±0.10}	0.25 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4
ERJP08	3.20+0.05	1.60+0.05	0.40 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10
ERJP14	3.20 ^{±0.20}	2.50 ^{±0.20}	0.35 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16



Anti-Surge Thick Film Chip Resistors

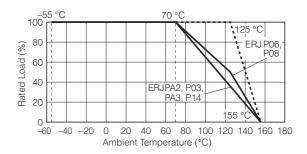
Ratings	S E							
Part No. (inch size)	Power Rating ⁽³⁾ at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJPA2	0.20	50	100	±0.5, ±1	10 to 1M (E24, E96)	±100	-55 to +155	Grade 0
(0402)	0.20		100	±5	10 to 1M (E24)	±200	00 10 1 100	Grado o
				±0.5	10 to 1M (E24, E96)	±150		
ERJP03	0.20	150	200	±1	10 to 1M (E24, E96)	±200	-55 to +155	Grade 0
(0603)				±5	1 to 1M (E24)	R < 10 Ω : -150 to +400 10 Ω ≤ R : ±200		
ERJPA3	0.25	150	200	±0.5, ±1	10 to 1M (E24, E96)	±100	-55 to +155	Grade 0
(0603)	0.23	130	200	±5	1 to 1.5M (E24)	±200	-55 10 + 155	Grade 0
ERJP06				±0.5, ±1	10 to 1M (E24, E96)	R < 33 Ω : ±300 33 Ω≤ R : ±100		
(0805)	0.50	400	600	±5	1 to 3.3M (E24)	$\begin{array}{cccc} R < 10 \ \Omega & : -100 \ to +600 \\ 10 \ \Omega \leq R < 33 \ \Omega & : \pm 300 \\ 33 \ \Omega \leq R & : \pm 200 \end{array}$	-55 to +155	Grade 0
ERJP08				±0.5, ±1	10 to 1M (E24, E96)	±100		
(1206)	0.66	500	1000	±5	1 to 10M (E24)	R < 10 Ω : -100 to +600 10 Ω ≤ R : ±200	-55 to +155	Grade 0
ERJP14				±0.5, ±1	10 to 1M (E24, E96)	±100		
(1210)	0.50	200	400	±5	1 to 1M (E24)	R < 10 Ω : -100 to +600 10 Ω ≤ R : ±200	-55 to +155	Grade 0

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=VPower Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

* When the temperature of ERJP14 is 155 °C or less, the derating start temperature can be changed to 125 °C. (See the dotted line)

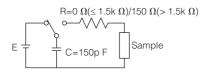


⁽²⁾ Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

⁽³⁾ Use it on the condition that the case temperature is below the upper category temperature.

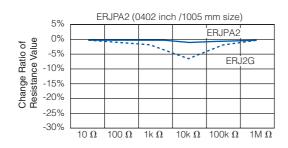
Anti-Surge Thick Film Chip Resistors

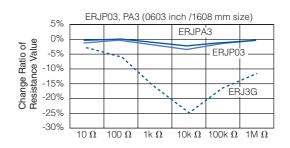
ESD Characteristic

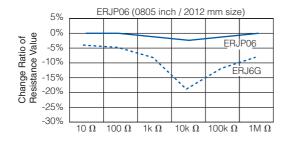


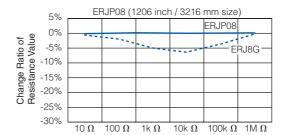
0402 inch size : $E=\pm 1k V$ 0603, 0805, 1206, 1210 inch size : $E=\pm 3k V$

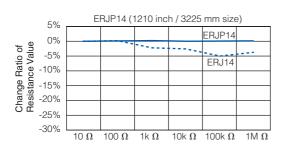
Anti-Surge Thick Film Chip Resistors(ERJP Type)Thick Film Chip Resistors(ERJ Type)











Performance		
Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C (ERJPA2 : +125 °C)
Overload	±2% Only when it is ERJP03 (D), P14 (D): ±0.5%	ERJP06 : Rated Voltag×1.77, 5 s ERJPA2, ERJPA3, ERJP08 : Rated Voltag×2.0, 5 s ERJP03, ERJP14 : Rated Voltag×2.5, 5 s
Resistance to Soldering Heat	D: ±0.5%, F, J: ±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30 min.) / +155 °C (30 min.) , 100 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3% Only when it is ERJP03 (D), P14 (D) : ±1%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3% Only when it is ERJP03 (D), P14 (D) : ±1%	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Anti-Pulse Thick Film Chip Resistors

Anti-Pulse Thick Film Chip Resistors

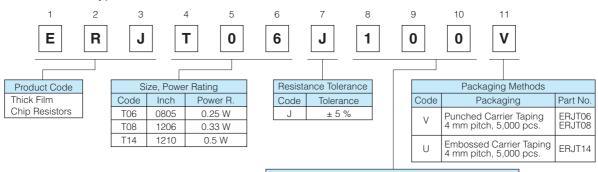
Type: **ERJ T06, T08, T14** ERJ T14L

Features

- Anti-Pulse characteristics
 - High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability
 - Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power · · · 0.25W : 0805 inch / 2012 mm size (ERJT06)
 - 0.33W: 1206 inch / 3216 mm size (ERJT08)
 - 0.50W: 1210 inch / 3225 mm size (ERJT14, ERJT14L)
- Reference Standards…IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

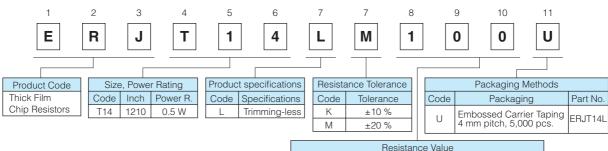
• ERJT06, T08, T14 Type



Resistance Value

The first two digits are significant figures of resistance and the third one denotes number of zeros following. Example: 222 \rightarrow 2.2 k Ω

ERJT14L Type

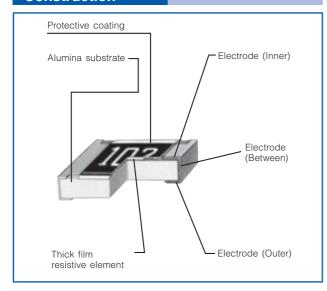


The first two digits are significant figures of resistance and the third one denotes number of zeros following Example: 222 \rightarrow 2.2 k Ω

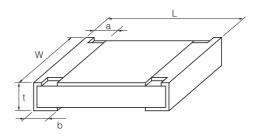
^{*} Please contact us for 2012 (mm) and 3216 (mm) size trimming-less types.

Anti-Pulse Thick Film Chip Resistors

Construction



Dimensions in mm (not to scale)



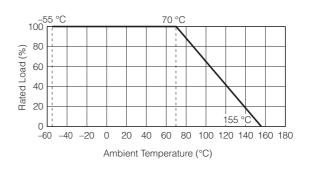
Part No.		Mass (Weight)				
(inch size)	L	W	а	b	t	[g/1000 pcs.]
ERJT06 (0805)	2.00 ^{±0.20}	1.25 ^{±0.10}	0.25 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4
ERJT08 (1206)	3.20+0.05	1.60+0.05	0.40 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10
ERJT14 ERJT14L (1210)	3.20 ^{±0.20}	2.50 ^{±0.20}	0.35 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16

Ratings	Ratings								
Part No. (inch size)	Power Rating at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)		
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	Less than 10 Ω : -100 to +600 Less than 33 Ω : ±300 More than 33 Ω : ±200	-55 to +155		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	Less than 10 Ω : –100 to +600 More than 10 Ω : ±200	-55 to +155		
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	Less than 10 Ω : –100 to +600 More than 10 Ω : ±200	-55 to +155		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	Less than 10 Ω : –100 to +600 More than 10 Ω : ±200	-55 to +155		

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

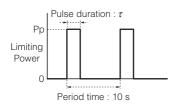


⁽²⁾ Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV= $2.5 \times RCWV$ or max. Overload Voltage listed above whichever less.

Anti-Pulse Thick Film Chip Resistors

Limiting Power Curve

• In rush pulse Characteristic

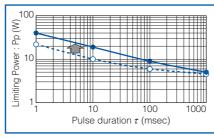


Test cycle: 1000 cycles

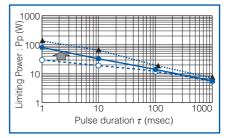
Spec : Resistance value = within ±5%

- ▲ : Anti-Pulse Thick Film Chip Resistors (ERJT14L Type)
- : Anti-Pulse Thick Film Chip Resistors (ERJT Type)
- : Thick Film Chip Resistors (ERJ Type)

- ERJT06 (0805 inch/2012 mm size)
- ERJT08 (1206 inch/3216 mm size)



• ERJT14,ERJT14L (1210 inch/3225 mm size)



* Please contact us for 2012 (mm) and 3216 (mm) size trimming-less types.

Anti-Sulfurated Thick Film Chip Resistors

Anti-Sulfurated Thick Film Chip Resistors



Type: ERJ S02, S03, S06, S08, S14, S12, S1D, S1T

(Au-based inner electrode type)

Type: ERJ U01, U02, U03, U06, U08, U14, U12,

U1D, U1T, U6S, U6Q

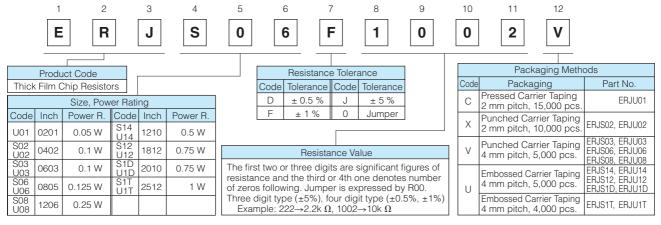
(Ag-Pd-based inner electrode type)

Features

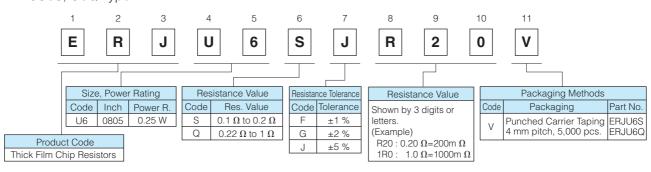
- High resistance to sulfurization achieved by adopting an Au-based inner electrode (ERJS type) and Ag-Pd-based inner electrode (ERJU type)
- High reliability
 Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- Low Resistance type...ERJU6S, U6Q : 0.1 Ω to 1.0 Ω
- Reference Standard···IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified (Exemption ERJU01)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files

Explanation of Part Numbers

• ERJU01 to ERJU1T, ERJS02 to ERJS1T Type

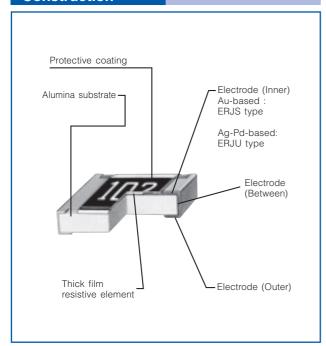


ERJU6S, U6Q Type

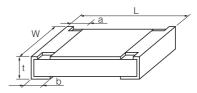


Anti-Sulfurated Thick Film Chip Resistors

Construction



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)					
Tarrino.	L	W	а	b	t	[g/1000 pcs.]	
ERJU01	0.60 ^{±0.03}	0.30 ^{±0.03}	0.10 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.15	
ERJS02 ERJU02	1.00 ^{±0.05}	0.50 ^{±0.05}	0.20 ^{±0.10}	0.25 ^{±0.10}	0.35 ^{±0.05}	0.8	
ERJS03 ERJU03	1.60 ^{±0.15}	0.80+0.15	0.30 ^{±0.20}	0.30 ^{±0.15}	0.45 ^{±0.10}	2	
ERJS06 ERJU06	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4	
ERJU6□	2.00 ^{±0.20}	1.25 ^{±0.10}	0.45 ^{±0.20}	0.45 ^{±0.20}	0.55 ^{±0.10}	6	
ERJS08 ERJU08	3.20 +0.05	1.60+0.05	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10	
ERJS14 ERJU14	3.20 ^{±0.20}	2.50 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16	
ERJS12 ERJU12	4.50 ^{±0.20}	3.20 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	27	
ERJS1D ERJU1D	5.00 ^{±0.20}	2.50 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	27	
ERJS1T ERJU1T	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	45	

Ratings									
Part No. (inch size)	Power Rating ⁽³⁾ at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Ra	stance ange (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1M 1 to 1M	(E24, E96) (E24)		-55 to +125	_
ERJS02 ERJU02 (0402)	0.1	50	100	±0.5, ±1 ±5	1 to 1M 1 to 3.3M	(E24, E96) (E24)	<10 Ω:	-55 to +155	Grade 0
ERJS03 ERJU03 (0603)	0.1	75	150	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)	-100 to +600	-55 to +155	Grade 0
ERJS06 ERJU06 (0805)	0.125	150	200	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)	10 Ω to 1M Ω:	-55 to +155	Grade 0
ERJS08 ERJU08 (1206)	0.25	200	400	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)	±200(±5%) ±100(±0.5, ±1%)*	-55 to +155	Grade 0
ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)	*ERJU01, ERJS02, ERJU02:	-55 to +155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)	±200 1M Ω<: -400 to +150	-55 to +155	Grade 0
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)		-55 to +155	Grade 0
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1M 1 to 10M	(E24, E96) (E24)		-55 to +155	Grade 0

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (3) Use it on the condition that the case temperature is below the upper category temperature.

[Low Resistance type]

Part No. (inch size)	PowerRating ⁽¹⁾ at 70 °C (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJU6S (0805)	0.25 ±1. ±2. ±5		0.1 to 0.2 (E24)	±150	-55 to +155	Grade 0
ERJU6Q (0805)	0.23	±1, ±2, ±3	0.22 to 1 (E24)	±130	-55 (0 + 155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - · Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = Power Rating × Resistance Values.
- · Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

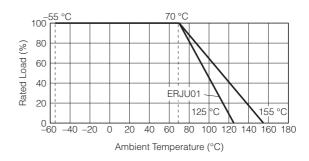
Anti-Sulfurated Thick Film Chip Resistors

[For Jumper]

Part No. (inch size)	Rated Current (A)	Maximum Overload Current (1) (A)
ERJU01 (0201)	0.5	1
ERJS02 ERJU02 (0402)	1	2
ERJS03 ERJU03 (0603)	1	2
ERJS06 ERJU06 (0805)		
ERJS08 ERJU08 (1206)		
ERJS14 ERJU14 (1210)	2	4
ERJS12 ERJU12 (1812)	2	4
ERJS1D ERJU1D (2012)		
ERJS1T ERJU1T		

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



(1) Overload test current

Performance

• ERJU01 to ERJU1T, ERJS02 to ERJS1T Type

Test Item	Performance Requirements		Test Conditions
lest item	Resistor type	Jumper type	lest Conditions
Resistance	Within Specified Tolerance	100m 12 or less	20 °C
T. C. R.	Within Specified T. C. R.	200m Ω or less	+25 °C/+155 °C (ERJU01 : +25 °C/+125 °C)
Overload	±2%	100m Ω or less	Rated Voltage × 2.5, 5s Jumper type: Max. Overload Current, 5 s
Resistance to Soldering Heat	±1%	100m Ω or less	270 °C, 10 s
Rapid Change of Temperature	±1%	100m Ω or less	-55 °C (30min.) / +155 °C (ERJU01: +125 °C) (30min.), 100 cycles
High Temperature Exposure	±1%	100m Ω or less	+155 °C (ERJU01 : +125 °C), 1000 h
Damp Heat, Steady State	±1%	100m Ω or less	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±3%	100m Ω or less	60 °C, 90% to 95 %RH, Rated Voltage (Jumper type : Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000h
Endurance at 70 °C	±3%	100m Ω or less	70 °C, Rated Voltage (Jumper type : Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000 h

• ERJU6S, U6Q Type

Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±1%	Rated Voltage × 2.5, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30min.) / +125 °C (30min.), 100 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

100



Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

Type: ERJ UP3, UP6, UP8

Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode structure and material
- ESD surge characteristics superior to standard metal film resistors
- High reliability

Metal glaze thick film resistive element and three layers of electrodes

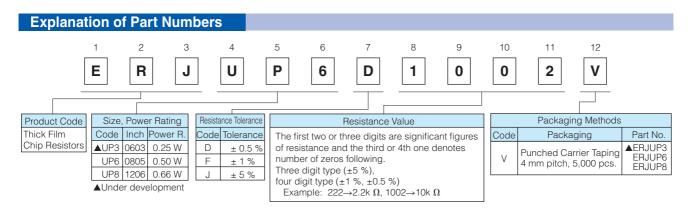
- Suitable for both reflow and flow soldering
- ◆ High power ··· 0.25 W : 0603 inch / 1608 mm size (ERJUP3)

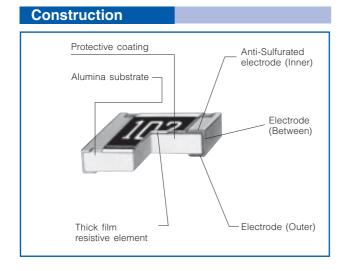
0.50 W: 0805 inch / 2012 mm size (ERJUP6)

0.66 W: 1206 inch / 3216 mm size (ERJUP8)

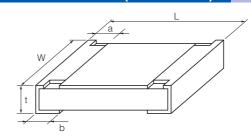
- Reference Standards… IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified
- RoHS compliant

■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files









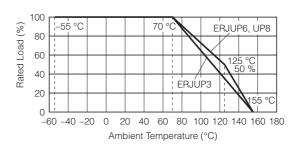
Part No.		Mass (Weight)				
Part No.	L	W	а	b	t	[g/1000 pcs.]
▲ERJUP3	1.60 ^{±0.15}	0.80+0.15	0.15+0.15	0.25 ^{±0.10}	0.45 ^{±0.10}	2
ERJUP6	2.00 ^{±0.20}	1.25 ^{±0.10}	0.25 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4
ERJUP8	3.20+0.05	1.60+0.05	0.40 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10

Ratings								
Part No. (inch size)	Power Rating ⁽³⁾ at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
▲ERJUP3	0.25	150	200	±0.5, ±1	10 to 1M (E24, E96)	±100	-55 to +155	Grade 0
(0603)	0.20	130	±5	±5	1 to 1.5M (E24)	±200	00 10 1 100	
ERJUP6				±0.5, ±1	10 to 1M (E24, E96)	±100		
(0805)	0.50	400	600	±5	1 to 3.3M (E24)	R < 10 Ω : -100 to +600 10 Ω ≤ R : \pm 200	–55 to +155	Grade 0
ERJUP8				±0.5, ±1	10 to 1M (E24, E96)	±100		
(1206)	0.66	500	1000	±5	1 to 10M (E24)	R < 10 Ω : -100 to +600 10 Ω ≤ R : \pm 200	-55 to +155	Grade 0

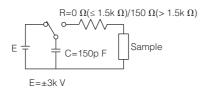
- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (3) Use it on the condition that the case temperature is below the upper category temperature.

Power Derating Curve

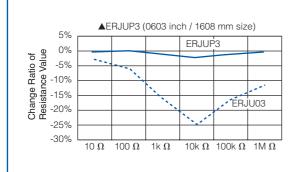
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

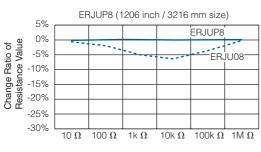


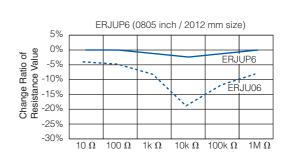
ESD Characteristic



Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type (ERJUP Type) Anti-Sulfurated Thick Film Chip Resistors (ERJU Type)









Panasonic Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

Performance		
Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C
Overload	±2%	ERJUP6 : Rated Voltage × 1.77, 5 s ▲ERJUP3, ERJUP8 : Rated Voltage × 2.0, 5 s
Resistance to Soldering Heat	D : ±0.5% F, J : ±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95%RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95%RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type



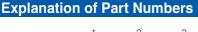
Type: ERJ C1

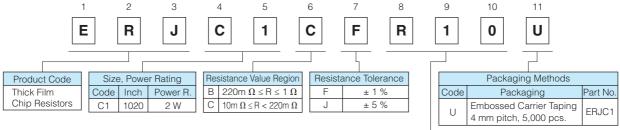
Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode structure and material
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 qualified
- RoHS compliant

Recommended Applications

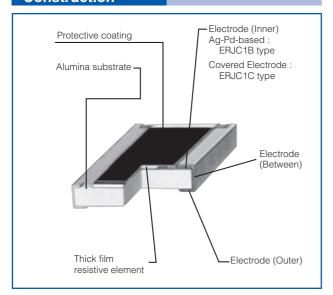
- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files



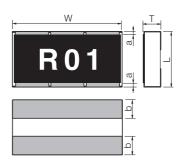


Resistance Value Shown by 3 digits or letters. Only when it is impossible, shown by 4 digits or letters (ex.) R01 : 0.01 Ω = 10m Ω R015 : 0.015 Ω = 15m Ω

Construction



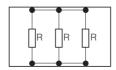
Dimensions in mm (not to scale)



Part No.		Mass (Weight)				
rait No.			а	b	[g/1000 pcs.]	
ERJC1B	2.50±0.20 5.00±0.20		0 55 : 0 20	0.35±0.20	0.90±0.20	27
ERJC1C	2.50±0.20	5.00±0.20	0.55±0.20	0.60±0.20	0.90±0.20	21

Circuit Configuration





Ratings

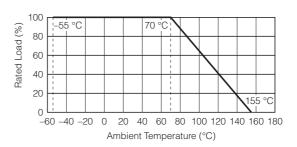
Part No. (inch size)	Power Rating at 70 °C (1) (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJC1	2	±1	10m to 1	$\begin{array}{ll} 10m\Omega & \leq R < 22m\Omega \ : \pm 350 \\ 22m\Omega & \leq R < 47m\Omega \ : \pm 200 \\ 47m\Omega & \leq R < 100m\Omega : \pm 150 \\ 100m\Omega & \leq R \leq 1\Omega \ : \pm 100 \end{array}$	-55 to +155	
(1020)	۷	±5	(E24)	$\begin{array}{ccc} 10m \; \Omega & \leq R < 22m \; \Omega & : \pm 350 \\ 22m \; \Omega & \leq R < 1 \; \Omega & : \pm 200 \end{array}$	-33 t0 +133	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Values.}}$ Overload Test Voltage (OTV) shall be determined from OTV = Specified Magnification (refer to performance) × RCWV.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

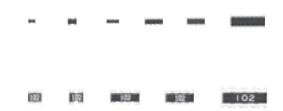


Perfomance		
Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.0, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±2%	-55 °C (30min.) / +125 °C (30min.), 1000 cycles
High Temperature Exposure	±1%	+155 °C, 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95 %RH, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage, 1.5 h ON/0.5 h OFF cycle, 1000 h

Panasonic

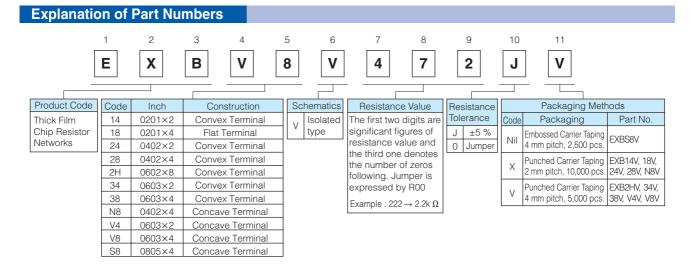
Chip Resistor Array

Type: **EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V**

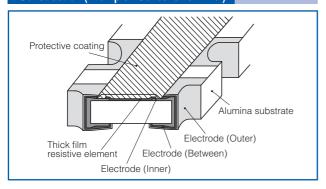


Features

- High density
 - 2 resistors in 0.8 mm \times 0.6 mm size / 0302 inch size : EXB14V
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, EXBN8V
 - 8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXB2HV
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, EXBV4V
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, EXBV8V
 - 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency
 - Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard...IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 qualified (EXB2, EXB3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

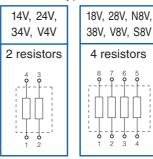


Construction (Example : Concave Terminal)



Schematics

Isolated type





Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W / element)	Limiting Element Voltage (1) (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1M (E24)		-55 to +125	_
EXB18V (0201×2)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1M (E24)		-55 to +125	_
EXB24V (0402×2)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1
EXB28V (0402×4)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1M (E24)	<10 Ω : -200 to +600	-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1
EXB38V (0603×4)	0.063	50	100	±5	1 to 1M (E24)	10 Ω to1M Ω : ± 200	-55 to +125	Grade 1
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1M (E24)		-55 to +125	-
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1M (E24)		-55 to +125	-
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1M (E24)		-55 to +125	
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1M (E24)		-55 to +125	_

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

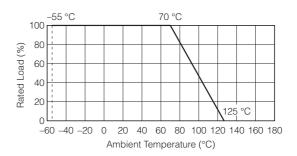
[For Jumper]

Part No. (inch size)	Rated Current (A / element)	Maximum Overload Current ⁽¹⁾ (A)
EXB14V (0201×2)	0.5	1
EXB18V (0201×4)	0.5	1
EXB24V (0402×2)	1	2
EXB28V (0402×4)	1	2
EXB2HV (0602×8)	1	2
EXB34V (0603×2)	1	2
EXB38V (0603×4)	1	2
EXBN8V (0402×4)	1	2
EXBV4V (0603×2)	1	2
EXBV8V (0603×4)	1	2
EXBS8V (0805×4)	2	4
(1) Overland test		

⁽¹⁾ Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

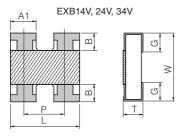


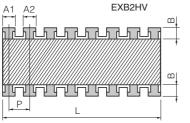
⁽²⁾ Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

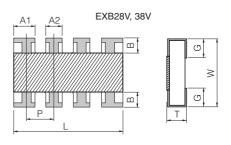
Panasonic

Dimensions in mm (not to scale)

(1) Convex Terminal type







Part No.	Dimensions (mm)						Mass (Weight)		
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXB14V (0201×2)	0.80 ^{±0.10}	0.60 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	_	0.15 ^{±0.10}	(0.50)	0.15 ^{±0.10}	0.5
EXB24V (0402×2)	1.00 ^{±0.10}	1.00 ^{±0.10}	0.35 ^{±0.10}	0.40 ^{±0.10}	_	0.18 ^{±0.10}	(0.65)	0.25 ^{±0.10}	1.2
EXB28V (0402×4)	2.00 ^{±0.10}	1.00 ^{±0.10}	0.35 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.20 ^{±0.10}	(0.50)	0.25 ^{±0.10}	2.0
EXB2HV (0602×8)	3.80 ^{±0.10}	1.60 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	0.30 ^{±0.10}	(0.50)	0.30 ^{±0.10}	9.0
EXB34V (0603×2)	1.60 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	_	0.30 ^{±0.20}	(0.80)	0.30 ^{±0.20}	3.5
EXB38V (0603×4)	3.20 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	0.45 ^{±0.15}	0.30 ^{±0.20}	(0.80)	0.35 ^{±0.20}	7.0

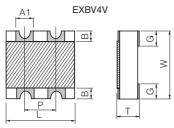
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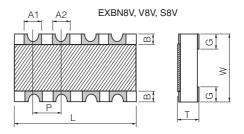
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() Reference

(2) Concave Terminal type

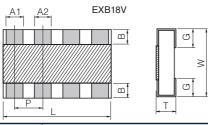




Part No.		Dimensions (mm)							Mass (Weight)
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXBN8V (0402×4)	2.00 ^{±0.10}	1.00 ^{±0.10}	0.45 ^{±0.10}	0.30 ^{±0.10}	0.30 ^{±0.10}	0.20 ^{±0.15}	(0.50)	0.30 ^{±0.15}	3.0
EXBV4V (0603×2)	1.60+0.20	1.60+0.20	0.60 ^{±0.10}	0.60 ^{±0.10}	_	0.30 ^{±0.15}	(0.80)	0.45 ^{±0.15}	5.0
EXBV8V (0603×4)	3.20+0.20	1.60+0.20	0.60 ^{±0.10}	0.60 ^{±0.10}	0.60 ^{±0.10}	0.30 ^{±0.15}	(0.80)	0.45 ^{±0.15}	10
EXBS8V (0805×4)	5.08+0.20	2.20+0.20	0.70 ^{±0.20}	0.80 ^{±0.15}	0.80 ^{±0.15}	0.50 ^{±0.15}	(1.27)	0.55 ^{±0.15}	30

() Reference

(3) Flat Terminal type



Part No.	Dimensions (mm)							Mass (Weight)	
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXB18V (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference



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	D (
Test Item	Performance	Test Conditions
	Requirements	
Resistance Within Specified		20 °C
	Tolerance	
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overland	. 00/	Rated Voltage × 2.5, 5 s
Overload	±2%	Jumper type: Max. Overload Current, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30min.) / +125 °C (30min.), 100 cycles
High Temperature Exposure	±1%	+125 °C , 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	. 20/	60 °C, 90% to 95 %RH, Rated Voltage (Jumper type: Rated Current),
Load Life in Humidity	±3%	1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage(Jumper type: Rated Current),
Endurance at 70 °C	±3%	1.5 h ON/0.5 h OFF cycle, 1000 h

Anti-Sulfurated Chip Resistor Array

Anti-Sulfurated Chip Resistor Array

Type: **EXB U14, U18, U24, U28,**

U2H, U34, U38



Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density

2 resistors in 0.8 mm \times 0.6 mm size / 0302 inch size : EXBU14

4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18

2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24

4 resistors in 2.0 mm \times 1.0 mm size / 0804 inch size : EXBU28

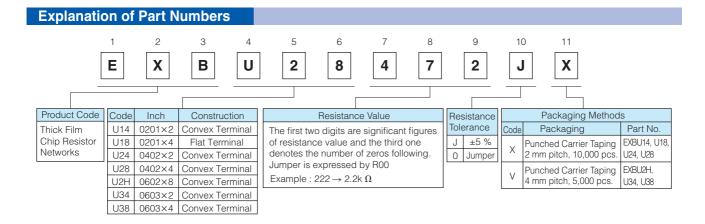
4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28

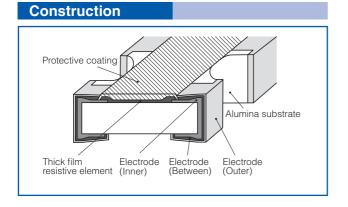
8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXBU2H

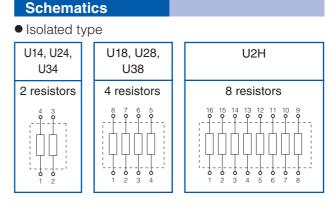
2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34

4 resistors in 3.2 mm \times 1.6 mm size / 1206 inch size : EXBU38

- Improvement of placement efficiency
 - Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard…IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 qualified (EXBU2, EXBU3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files







Anti-Sulfurated Chip Resistor Array

Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W / element)	Limiting Element Voltage (1) (V)	Maximum Overload Voltage (2)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1M (E24)		-55 to +125	_
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1M (E24)		-55 to +125	-
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1M (E24)	<10 Ω : -200 to +600	-55 to +125	Grade 1
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1M (E24)	$10 \Omega \text{ to 1M } \Omega$: ± 200	-55 to +125	Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1M (E24)		-55 to +125	Grade 1

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\frac{1}{2}\) Power Rating \(\times\) Resistance Values, or Limiting Element Voltage listed above, whichever less.

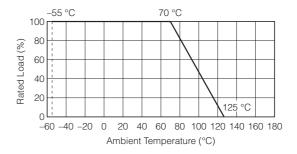
[For Jumper]

Part No. (inch size)	Rated Current (A / element)	Maximum Overload Current (1) (A)
EXBU24		
(0402×2)		
EXBU28		
(0402×4)		
EXBU2H	4	2
(0602×8)	I I	
EXBU34		
(0603×2)		
EXBU38		
(0603×4)		

⁽¹⁾ Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

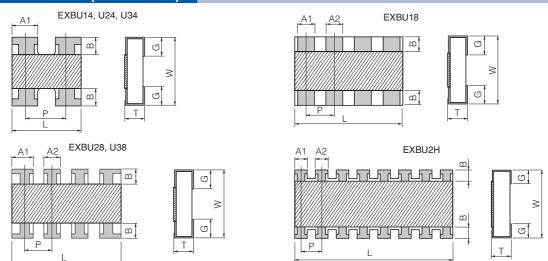


⁽²⁾ Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.



Anti-Sulfurated Chip Resistor Array

Dimensions in mm (not to scale)



Part No.	Dimensions (mm)											
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]			
EXBU14 (0201×2)	0.80 ^{±0.10}	0.60 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	_	0.15 ^{±0.10}	(0.50)	0.15 ^{±0.10}	0.5			
EXBU18 (0201×4)	1.40 ^{±0.10}	0.60 ^{±0.10}	0.35 ^{±0.10}	0.20 ^{±0.10}	0.20 ^{±0.10}	0.10 ^{±0.10}	(0.40)	0.20 ^{±0.10}	1.0			
EXBU24 (0402×2)	1.00 ^{±0.10}	1.00 ^{±0.10}	0.35 ^{±0.10}	0.40 ^{±0.10}	_	0.18 ^{±0.10}	(0.65)	0.25 ^{±0.10}	1.2			
EXBU28 (0402×4)	2.00 ^{±0.10}	1.00 ^{±0.10}	0.35 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.20 ^{±0.10}	(0.50)	0.25 ^{±0.10}	2.0			
EXBU2H (0602×8)	3.80 ^{±0.10}	1.60 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	0.30 ^{±0.10}	(0.50)	0.30 ^{±0.10}	9.0			
EXBU34 (0603×2)	1.60 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	_	0.30 ^{±0.20}	(0.80)	0.30 ^{±0.20}	3.5			
EXBU38 (0603×4)	3.20 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	0.45 ^{±0.15}	0.30 ^{±0.20}	(0.80)	0.35 ^{±0.20}	7.0			

) Reference

Perfomance		
Test Item	Performance Requirements	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2%	Rated Voltage × 2.5, 5 s Jumper type: Max. Overload Current, 5 s
Resistance to Soldering Heat	±1%	270 °C, 10 s
Rapid Change of Temperature	±1%	-55 °C (30min.) / +125 °C (30min.), 100 cycles
High Temperature Exposure	±1%	+125 °C , 1000 h
Damp Heat, Steady State	±1%	60 °C, 90% to 95 %RH, 1000 h
Load Life in Humidity	±3%	60 °C, 90% to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3%	70 °C, Rated Voltage(Jumper type: Rated Current), 1.5 h ON/0.5 h OFF cycle, 1000 h



Chip Resistor Networks

Type: **EXBD EXBE**

EXBA EXBQ



Features

- High density placing for digital signal circuits
 - · Bussed 8 or 15 resistors for pull up/down circuits

EXBD: $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$, 0.635 mm pitch

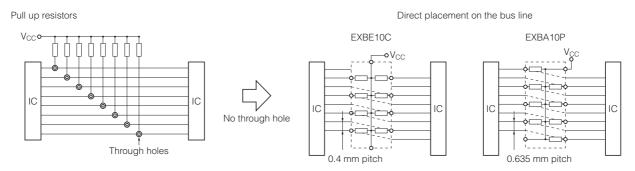
EXBE: $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$, 0.8 mm pitch

EXBA: 6.4 mm \times 3.1 mm \times 0.55 mm, 1.27 mm pitch

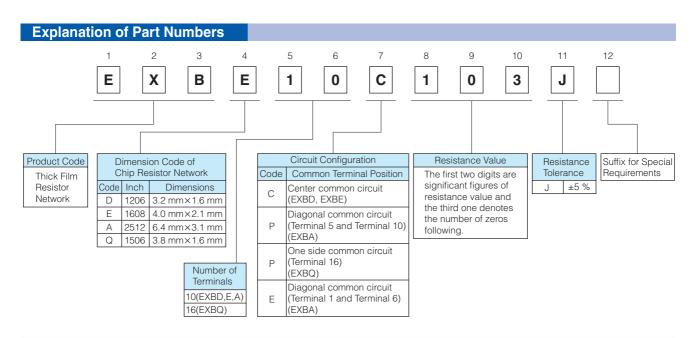
EXBQ: $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}, 0.5 \text{ mm}$ pitch

- · Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard...IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

[High density placing]

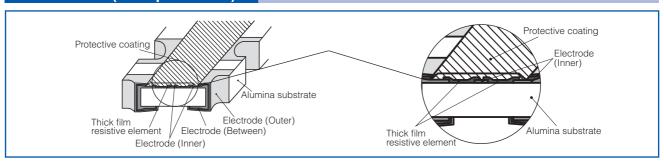


■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

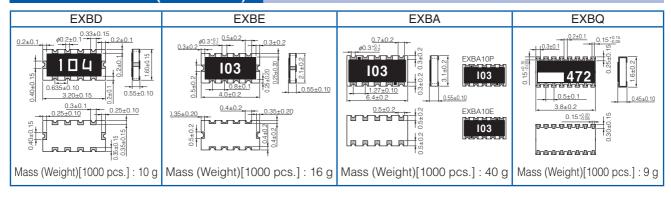


Chip Resistor Networks

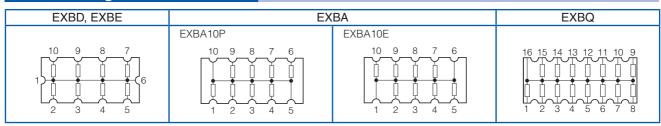
Construction (Example: EXBD)



Dimensions in mm (not to scale)



Circuit Configuration



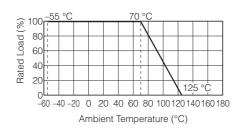
Ratings

Item		Specifi	cations			
Series	EXBD	EXBE	EXBA	EXBQ		
Resistance Range		47 Ω to 1 M Ω (E12)		100 Ω to 470 k Ω (E6 series)		
Resistance Tolerance		±5	5%			
Number of Terminals		10 terminals		16 terminals		
Number of Resistors		15 element				
Power Rating at 70 °C	0.05 W/element	/element	0.025 W/element			
Limiting Element Voltage ⁽¹⁾	25	5V	50 V	25V		
Maximum Overload Voltage ⁽²⁾	50	100 V	50 V			
T. C. R.		±200 ×	10 ⁻⁶ / °C			
Category Temperature Range	−55 °C to +125 °C					

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



⁽²⁾ Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 x RCWV* or Maximum Overload Voltage listed above whichever less.



Chip Attenuator

Type: **EXB 14AT**

EXB 24AT



Features

- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm × 0.6 mm), EXB24AT (1.0 mm × 1.0 mm)
- Reduced mounting area:

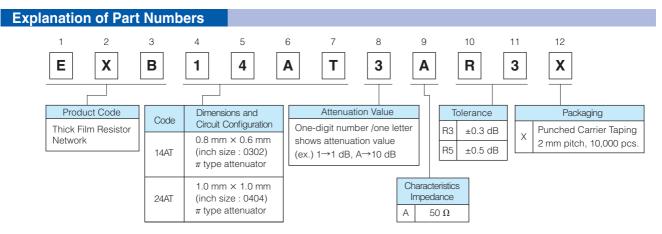
EXB14AT: About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors

EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors

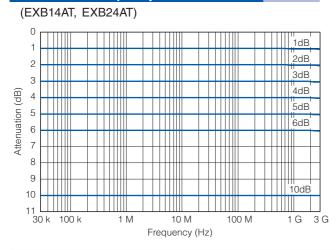
- Mounting cost reduction: (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

Recommended Applications

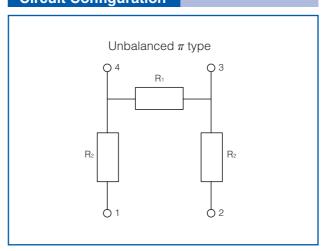
- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files



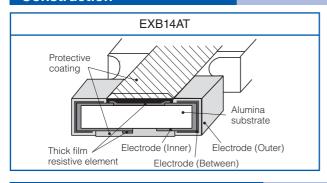
Attenuation-Frequency Characteristics

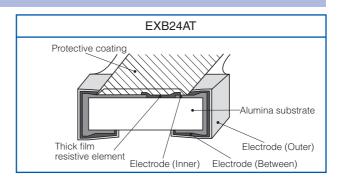


Circuit Configuration

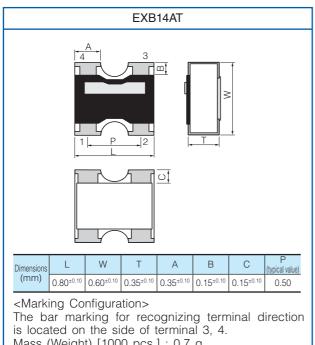


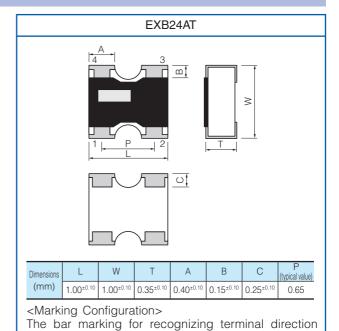
Construction





Dimensions in mm (not to scale)





is located on the side of terminal 4.

-55 °C to +125 °C

Mass (Weight) [1000 pcs.]: 1.1 g

Mass (Weight) [1000 pcs.] : 0.7 g

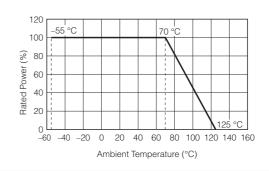
Ratings						
Part No.	EXB14AT, EXB24AT					
Attenuation Value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*					
Attenuation Value Tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5 dB : ±0.3 dB 6 dB, 10 dB : ±0.5 dB					
Characteristic Impedance	50 Ω					
Power Rating	0.04 W /package					
Frequency Range at 70 °C	DC to 3.0 GHz					
VSWR (Voltage Standing Wave Ratio)	1.3 max.					
Number of Resistors	3 resistors					
Number of Terminals	4 terminals					

Category Temperature Range

* Please inquire about the other Attenuator value

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

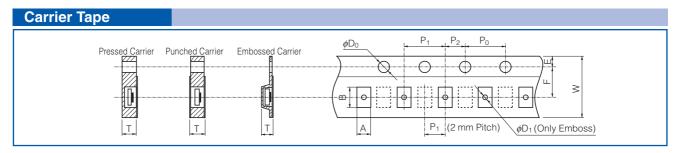


Surface N	Mount Resistors Serie	es	Pac	kaging (Standard	Quantity : pcs./	reel)
Products	Part No.	Size mm (inch)	Pressed Carrier Taping (2 mm pitch)	Punched Carrier Taping (2 mm pitch)	Punched Carrier Taping (4 mm pitch)	Embossed Carrier Taping (4 mm pitch)
	ERJXGN	0402(01005)	20,000 *	_	<u>—</u>	4,0000 **
	ERJ1GN	0603(0201)	15,000	_		_
	ERJ2GE	1005(0402)	_	10,000, 20,000		_
	ERJ3GE	1608(0603)	_	_	5,000	_
Thick Film	ERJ6GE	2012(0805)	_	_	5,000	_
Chip Resistors	ERJ8GE	3216(1206)	_	_	5,000	_
	ERJ14	3225(1210)	_	_	_	5,000
	ERJ12	4532(1812)	_	_	_	5,000
	ERJ12Z	5025(2010)	_	_	_	5,000
	ERJ1T	6432(2512)	_	_	_	4,000
	ERJXGN	0402(01005)	20,000 *	_	_	4,0000 **
	ERJ1GN/1RH	0603(0201)	15,000	_	_	_
	ERJ2RC/2RH/2RK	1005(0402)	_	10,000	<u> </u>	_
	ERJ3RB/3RE/3EK	1608(0603)	_	_	5,000	_
Precision	ERJ6RB/6RE/6EN	2012(0805)	_	_	5,000	_
Thick Film Chip Resistors	ERJ8EN	3216(1206)	_	_	5,000	_
2111/2111212121212	ERJ14N	3225(1210)	_	_	_	5,000
	ERJ12N	4532(1812)	_	_	_	5,000
	ERJ12S	5025(2010)	_	_	_	5,000
	ERJ1TN	6432(2512)	_	_	_	4,000
	ERJ1TN 6432(2512) — — ERA1A 0603(0201) 15,000 —	_	_	_		
Metal Film (Thin Film)	ERA2A/2V	1005(0402)	_	10,000	_	_
Chip Resistors, High Reliability Type	ERA3A/3V	1608(0603)	_	_	5,000	_
/Anti-ESD Type	ERA6A/6V	2012(0805)	_	_	5,000	_
	ERA8A	3216(1206)	_	_	5,000	_
	ERJ2LW/2BW	1005(0402)	10,000	_	_	_
	ERJ2BS/2BQ	1005(0402)	_	10,000	_	_
	ERJ3L/3B/3R/L03	1608(0603)	_	_	5,000	_
Thick Film	ERJ6L/6B/6C ERJ6D/6R/L06	2012(0805)	_	_	5,000	_
Chip Resistors/	ERJ8B/8C/8R/L08	3216(1206)	_	_	5,000	_
Low Resistance Type	ERJ14B/14R/L14	3225(1210)	_	_	_	5,000
1,700	ERJ12R/L12	4532(1812)	_	_	_	5,000
	ERJ12Z/L1D	5025(2010)	_	_	_	5,000
	ERJ1TR	6432(2512)	_	_	_	4,000
	ERJL1W	6432(2512)	_	_	<u> </u>	3,000
	ERJMP2	3216(1206)	_	_	_	3,000
	ERJMP3	5025(2010)	_	_	_	3,000
Current Sensing	ERJMP4	6432(2512)	_	_	_	2,000
Resistors,	ERJMS4	6432(2512)	_	_	_	2,000
Metal Plate Type	ERJMS6	6468(2526)	_	_	_	1,000 (8 mm Pitch)
	ERJMB1	2550(1020)	_	_	_	3,000
	ERJM1W	6432(2512)	_	_	_	3,000
Current Sensing Resistors, Metal Foil Type	ERJMFBA	1005(0402)	_	10,000	_	_

* W8P2: Width 8 mm, Pitch 2 mm, ** W4P1: Width 4 mm, Pitch 1 mm (1) Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

Curtoso	Aquat Dagistara Caria	0	Doo	Logina (Ctandors	d Ougatity , page /	rool)
Surface N	Mount Resistors Serie	:S			d Quantity : pcs./i	-
Products	Part No.	Size mm (inch)	Pressed Carrier Taping (2 mm pitch)	Punched Carrier Taping (2 mm pitch)	Punched Carrier Taping (4 mm pitch)	Embossed Carrier Taping (4 mm pitch)
	ERJA1	3264(1225)	_	_		4,000
High Power Chip Resistors/	ERJB1/ERJC1 ⁽¹⁾ ERJC1 ⁽²⁾	2550(1020)	_	_	_	5,000
Wide Terminal Type	ERJB2/ERJD2 ⁽²⁾	1632(0612)	_	_	5,000	
	ERJB3	1220(0508)	_	_	5,000	_
	ERJPA2	1005(0402)	_	10,000		_
High Precision/	ERJPB3/P03/PA3	1608(0603)	_	_	5,000	_
Anti-Surge Thick Film	ERJPB6/P06	2012(0805)		_	5,000	_
Chip Resistors	ERJP08	3216(1206)		_	5,000	_
	ERJP14	3225(1210)		_	_	5,000
Anti-Pulse	ERJT06	2012(0805)	_	_	5,000	_
Thick Film	ERJT08	3216(1206)	_	_	5,000	_
Chip Resistors	ERJT14	3225(1210)	_	_	_	5,000
	ERJU01	0603(0201)	15,000	_	_	_
	ERJS02/U02	1005(0402)	_	10,000	_	_
	ERJS03/U03	1608(0603)	_	_	5,000	_
Anti-Sulfurated	ERJS06/U06 ERJU6S/U6Q/UP6	2012(0805)	_	_	5,000	_
Thick Film Chip Resistors	ERJS08/U08/UP8	3216(1206)	_	_	5,000	_
Chip nesistors	ERJS14/U14	3225(1210)	_	_	_	5,000
	ERJS12/U12	4532(1812)	_	_	_	5,000
	ERJS1D/U1D	5025(2010)	_	_	_	5,000
	ERJS1T/U1T	6432(2512)	_	_	_	4,000
	EXB14V	0806(0302)	_	10,000	_	_
	EXB24V	1010(0404)	_	10,000	_	_
	EXB34V	1616(0606)	_	_	5,000	_
	EXBV4V	1616(0606)	_	_	5,000	_
01: 5	EXB18V	1406(0502)		10,000	_	_
Chip Resistor Array	EXB28V	2010(0804)		10,000		_
, wy	EXBN8V	2010(0804)	_	10,000		
	EXB38V	3216(1206)	_	_	5,000	
	EXBV8V	3216(1206)		_	5,000	
	EXBS8V	5022(2009)	_			2,500
	EXB2HV	3816(1506)		_	5,000	_
	EXBU14	0806(0302)		10,000	_	
	EXBU18	1406(0502)		10,000		_
Anti-Sulfurated	EXBU24	1010(0404)		10,000	_	_
Chip Resistor	EXBU34	1616(0606)			5,000	
Array	EXBU28	2010(0804)	_	10,000	_	_
	EXBU38	3216(1206)	_	_	5,000	_
	EXBU2H	3816(1506)			5,000	
	EXBD	3216(1206)	_		5,000	
Chip Resistor	EXBE	4021(1608)				4,000
Networks	EXBA	6431(2512)				4,000
	EXBQ	3816(1506)	_	_	5,000	_
Chip Attenuator	EXB14AT	0806(0302)		10,000	_	
	EXB24AT	1010(0404)	_	10,000		

⁽¹⁾ Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type (2) Low TCR High Power Chip Resistors / Wide Terminal Type



Pressed Carrier Taping (2 mm Pitch)

Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / Anti-Surge / Anti-Sulfur

(Unit:mm)

	Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	ø D₀	Т
	ERJXGN	0402(01005)	0.24 ^{±0.03}	0.45 ^{±0.03}								0.31 ^{±0.05}
	ERJ1GN ERJ1R□ ERJU01 ERA1A	0603 (0201)	0.38 ^{±0.05}	0.68 ^{±0.05}	8.00 ^{±0.20}	3.50 ^{±0.05}	1.75 ^{±0.10}	2.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}	1.50+0.10	0.42 ^{±0.05}
_	ERJ2LW	1005(0402)	0.68 ^{±0.10}	1.20 ^{±0.10}								0.60 ^{±0.05}
	ERJ2BW	1005(0402)	0.67 ^{±0.10}	1.17 ^{±0.10}								0.61 ^{±0.05}

Punched Carrier Taping (2 mm Pitch)

Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / Anti-Surge / Anti-Sulfur / Metal Foil Type

(Unit: mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	φ D₀	Т
ERJ2□ ERJPA2 ERJ□□2 ERA2□	1005 (0402)	0.67 ^{±0.05}	1.17 ^{±0.05}	8.00 ^{±0.20}	3.50 ^{±0.05}	1.75 ^{±0.10}	2.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}	1.50+0.10	0.52 ^{±0.05}
ERJMFBA											0.60 ^{±0.05}

• Chip Resistor Array / Anti-Sulfurated Chip Resistor Array / Chip Attenuator

(Unit:mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	φ D ₀	Т
EXB14V EXB14AT	0806 (0302)	0.70+0.10	0.95 ^{+0.05} _{-0.10}								
EXB18V	1406(0502)	0.70_0.05	1.60 ^{±0.10}								
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20 ^{±0.10}	1.20 ^{±0.10}	8.00 ^{±0.20}	3.50 ^{±0.05}	1.75 ^{±0.10}	2.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}	1.50+0.10	0.52 ^{±0.05}
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20 ^{±0.10}								

Punched Carrier Taping (4 mm Pitch)

• Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / High Power / High Precision / Anti-Surge / Anti-Pulse / Anti-Sulfur

(Unit: mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	<i>φ</i> D ₀	Т
ERJ3□ ERJ3LW(10 mΩ) ERJ3BW ERJ□□3 ERA3□	1608 (0603)	1.10 ^{±0.10}	1.90 ^{±0.10}								0.70 ^{±0.05}
ERJ3LW(5 m Ω)											
ERJ6□ ERJ□□6 ERJU6S, U6Q ERA6□	2012 (0805)	1.65 ^{±0.15}	2.50 ^{±0.20}	0.000	0 TO :005	. == .0.10		0.00.005	1.00:010		0.84 ^{±0.05}
ERJB3	1220(0508)			8.00 ^{±0.20}	3.50 ^{±0.05}	1.75 ^{±0.10}	4.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}	1.50+0.10	
ERJ6BW	2012										
ERJ6LW ERJ6CW	(0805)	1.55 ^{±0.15}	2.30 ^{±0.20}								0.94 ^{±0.05}
ERJ8□ ERJ8□W ERJ□□8 ERA8A	3216 (1206)	2.00 ^{±0.15}	3.60 ^{±0.20}								0.84 ^{±0.05}
ERJB2 ERJD2	1632 (0612)										

• Chip Resistor Array / Anti-Sulfurated Chip Resistor Array / Chip Resistor Networks

(Unit:mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	φDo	Т
EXB34V EXBU34	1616(0606)	1.95 ^{±0.15}	1.95 ^{±0.20}	. 8.00 ^{±0.20}		1.75 ^{±0.10}	4.00 ^{±0.10}			1.50+0.10	
EXB38V EXBU38	3216(1206)		3.60 ^{±0.20}					2.00 ^{±0.05}	4.00 ^{±0.10}		0.70 ^{±0.05}
EXB2HV EXBU2H	3816(1506)		I /1 1()±0.13		3.50 ^{±0.05}						
EXBV4V	1616(0606)		1.95 ^{±0.20}			0					0.84 ^{±0.05}
EXBV8V	3216(1206)	2.00 ^{±0.20} 1.90 ^{±0.20}	3.60 ^{±0.20}								0.04
EXBD	3216(1206)		3.60 ^{±0.20}								0.84 ^{±0.10}
EXBQ	3816(1506)		4.10 ^{±0.20}								0.64 ^{±0.05}

Embossed Carrier Taping (1 mm Pitch)

Chip Resistors

(Unit:mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P_1	P_2	P_0	ø D₀	Т
ERJXGN	0402(01005)	0.25 ^{±0.05}	0.45 ^{±0.05}	4.00 ^{±0.20}	1.80 ^{±0.05}	0.90 ^{±0.10}	1.00 ^{±0.10}	1.00 ^{±0.10}	2.00 ^{±0.10}	$0.80^{\pm0.10}$	0.5 max.

Embossed Carrier Taping (4 mm Pitch)

• Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfur Pulse / Anti-Sulfur

(Unit:mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	φ D ₀	Т	φD ₁
ERJ14□ ERJ□14	3225 (1210)	2.80 ^{±0.20}	3.50 ^{±0.20}	8.00 ^{±0.30}	3.50 ^{±0.05}						1.00+8.10	
ERJ12□ ERJ□12	4532 (1812)	3.50 ^{±0.20}	4.80 ^{±0.20}									
ERJ12Z ERJ12S ERJ□1D	5025 (2010)	0.00±0.20	F 20±0.20								1.00 ^{±0.10}	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.80 ^{±0.20}		12.00 ^{±0.30}	5.50 ^{±0.20}	1.75 ^{±0.10}	4.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}			1.5 min.
ERJ1T□ ERJ□1T ERJL1W	6432 (2512)	3.60 ^{±0.20}	6.90 ^{±0.20}								1.60 ^{±0.10}	
ERJA1	3264(1225)	3.50 ^{±0.20}	6.80 ^{±0.20}								1.10 ^{±0.20}	Į.

Current Sensing Resistors, Metal Plate Type

(Unit : mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	ø D₀	Т	φD ₁
ERJMP2 (1m Ω)	3216(1206)										1.55 ^{±0.20}	_
ERJMP2 (2m Ω)	3216(1206)	1.90 ^{±0.20}	3.50 ^{±0.20}	8.00 ^{±0.30}	3.50 ^{±0.10}						1.40 ^{±0.20}	_
ERJMP2 (3 to 50m Ω)	3216(1206)										1.10 ^{±0.20}	_
ERJMP3 (1 to 2m Ω)	5025(2010)										1.55 ^{±0.20}	_
ERJMP3 (3 to 50m Ω)	5025(2010)	2.90 ^{±0.20}	5.40 ^{±0.20}	12.00 ^{±0.30}	5.50 ^{±0.10}	1.75 ^{±0.10}	4.00 ^{±0.10}	2.00 ^{±0.05}	$4.00^{\pm0.10}$	1.50+0.10	1.15 ^{±0.20}	_
ERJMB1	2550(1020)										1.55 ^{±0.20}	_
ERJMP4 (1 to 2m Ω)	6432(2512)										1.60 ^{±0.20}	1.5 min.
ERJMP4 (3 to 50m Ω)	6432(2512)	3.50 ^{±0.20}	6.90 ^{±0.20}	12.00 ^{±0.30}	5.50 ^{±0.10}						1.20 ^{±0.20}	_
ERJMS4	6432(2512)										1.60 ^{±0.20}	1.5 min.
ERJM1W	6432(2512)										1.80 ^{±0.20}	1.5 min.

Chip Resistor Array / Chip Resistor Networks

(Unit:mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P_0	ϕD_0	Т	φD ₁
EXBS8V											1.6 max.	
EXBE	4021(1608)	2.50 ^{±0.20}	4.40 ^{±0.20}	12.00 ^{±0.30}	$5.50^{\pm0.20}$	1.75 ^{±0.10}	4.00 ^{±0.10}	2.00 ^{±0.05}	$4.00^{\pm0.10}$	1.50+0.10	1 10±0.20	1.5 min.
EXBA	6431(2512)	3.50 ^{±0.20}	6.80 ^{±0.20}								1.10	



Embossed Carrier Taping (8 mm Pitch)

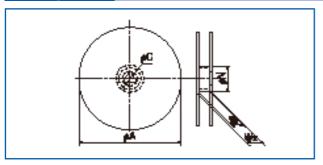
• Current Sensing Resistors, Metal Plate Type

(Unit:mm)

(Unit: mm)

Part No.	Size mm (inch)	А	В	W	F	Е	P ₁	P ₂	P ₀	ø D₀	Т	φD ₁
ERJMS6	6468(2526)	6.90 ^{±0.20}	7.50 ^{±0.20}	12.00 ^{±0.30}	5.50 ^{±0.05}	1.75 ^{±0.10}	8.00 ^{±0.10}	2.00 ^{±0.05}	4.00 ^{±0.10}	1.50+0.10	2.45 ^{±0.20}	1.5 min.

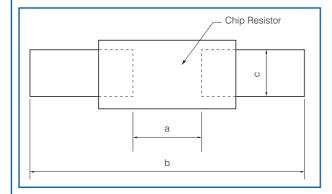
Taping Reel



Tape Width (W)	φΑ	φN	φC	W ₁	W_2
4mm Width	180.0 ^{±3.0}			4.5 ^{±0.5}	7.0 ^{±0.5}
8mm Width	180.0 0	60.0+1.0	13.0 ^{±0.2}	9.0+1.0	11.4 ^{±1.0}
12mm Width	100.0 -1.5		13.0	13.0+1.0	15.4 ^{±1.0}
24mm Width	380.0 ^{±2.0}	80.0 ^{±1.0}		25.4 ^{±1.0}	29.4 ^{±1.0}

Recommended Land Pattern

• An example of a land pattern for the Rectangular Type is shown below.



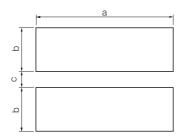
High power (double-sided resistive elements structure) type

ingir parrar (ara				
Part No.	Size	Din	nensions (r	nm)
ran No.	mm/inch	а	b	С
ERJ2LW/2BW	1005/0402	0.52	1.4 to 1.6	0.4 to 0.6
ERJ3LW/3BW	1608/0603	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1
ERJ6LW	2012/0805	0.6 to 0.8	3.2 to 3.8	1.1 to 1.4
ERJ6BW	2012/0805	0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (10 to 13 mΩ)	2012/0805	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (15 to 30 mΩ)	2012/0805	0.9 to 1.1	3.2 to 3.8	1.1 to 1.4
ERJ8BW				
ERJ8CW (10 to 16 mΩ)	3216/1206	1.2	1.3 to 1.8	
ERJ8CW (18 to 50 mΩ)	3216/1206	2.0 to 2.6	4.4 to 5.0	1.2 to 1.8

Size	D	imensions (mr	n)
mm/inch	а	b	С
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5

* ERJL1W

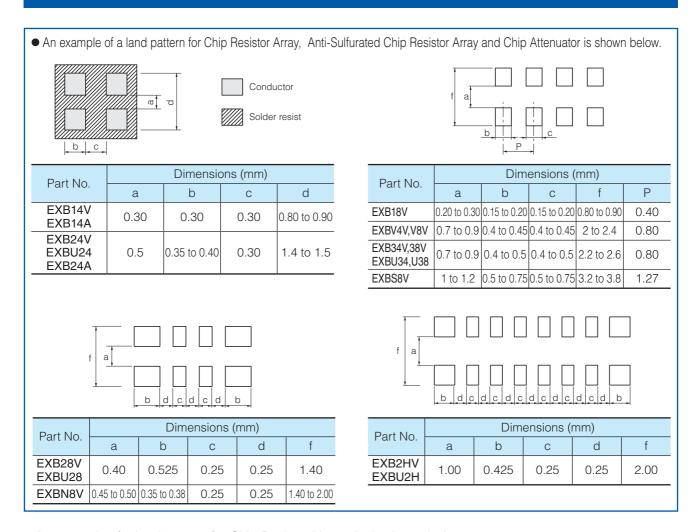
• An example of a land pattern for High Power Chip Resistors / Wide Terminal Type is shown below.



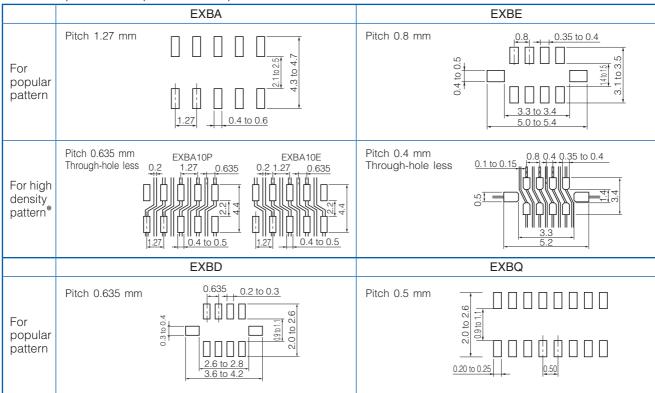
Part No.	Dimensions (mm)					
rait No.	а	b	С			
ERJA1	6.4	1.70	0.60			
ERJB1 ERJC1 ⁽¹⁾ ERJD1 ⁽²⁾	5.0	1.30	0.75			
ERJB2 ERJD2 ⁽²⁾	3.2	0.95	0.70			
ERJB3	2.0	0.80	0.60			

- (1) Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type
 (2) Low TCR High Power Chip Resistors /
- Wide Terminal Type

Surface Mount Resistors Land Pattern



• An example of a land pattern for Chip Resistor Networks is shown below.



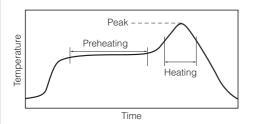
* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

Recommended Soldering Conditions

Recommendations and precautions are described below.

Rectagular Type

- Recommended soldering conditions for reflow
- · Reflow soldering shall be performed a maximum of two times.
- Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability before actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 °C to 160 °C	60 s to 120 s
Main heating	Above 200 °C	30 s to 40 s
Peak	235 ± 5 °C	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

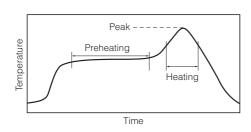
		Temperature	Time		
	Preheating	150 °C to 180 °C	60 s to 120 s		
	Main heating	Above 230 °C	30 s to 40 s		
	Peak	max. 260 °C	max. 10 s		

• Recommended soldering conditions for flow

	For so	ldering	For lead-free soldering		
	Temperature	Time	Temperature	Time	
Preheating	140 °C to 180 °C	60 s to 120 s	150 °C to 180 °C	60 s to 120 s	
Soldering	245 ± 5 °C	20 s to 30 s	max. 260 °C	max. 10 s	

• Chip Resistor Array, Chip Resistor Networks and Chip Attenuator

- Recommended soldering conditions for reflow
- Reflow soldering shall be performed a maximum of two times.
- · Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability before actual use.



For soldering (Example : Sn/Pb)

	Temperature	Time
Preheating	140 °C to 160 °C	60 s to 120 s
Main heating	Above 200 °C	30 s to 40 s
Peak	235 ± 5 °C	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 °C to 180 °C	60 s to 120 s
Main heating	Above 230 °C	30 s to 40 s
Peak	max. 260 °C	max. 10 s

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow soldering of EXBA series.

Panasonic Surface Mount Resistors Safety precautions

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- 1. Take measures against mechanical stress during and after mounting of Surface Mount Resistors (hereafter called the resistors) so as not to damage their electrodes and protective coatings.
 - Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- 2. Keep the rated power and ambient temperature within the specified derating curve.
 Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temperatures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and optimize them so as not to damage the boards and peripheral
 - Make sure to contact us before using the resistors under special conditions.
- 3. If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use.
 - Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- 4. Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the performance and reliability of the resistors.
- 5. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- 6. As the amount of applied solder becomes larger, the mechanical stress applied to the resistors increases, causing problems such as cracks and faulty characteristics. Avoid applying an excessive amounts of solder.
- 7. When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 8. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 9. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 10. Do not immerse the resistors in solvent for a long time. Before using solvent, carefully check the effects of immersion.
- 11. Transient voltage

components

- If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of Fixed Metal (Oxide) Film Resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions to complete the design or decide to use the resistors.
- 12. Do not apply excessive tension to the terminals.



Metal (Oxide) Film Resistors

Type: **ERG(X)S (Small size)** (0.5 W, 1 W, 2 W, 3 W, 5 W)

ERG(X)F (Anti-heat conducting for PCB)

(1 W, 2 W, 3 W, 5 W)



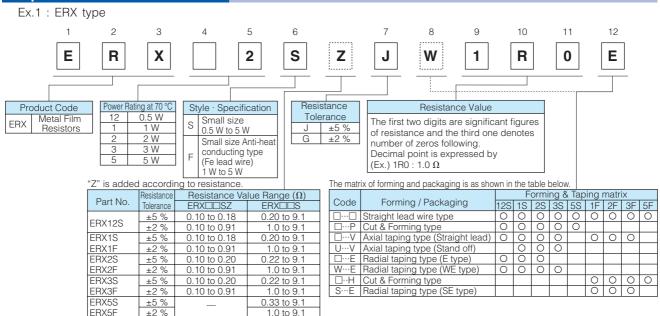
Features

- Miniaturized
 50 % smaller compared to existing models
- Non-flammable
- High Reliability
- Automatic Insertion
- Reference Standards

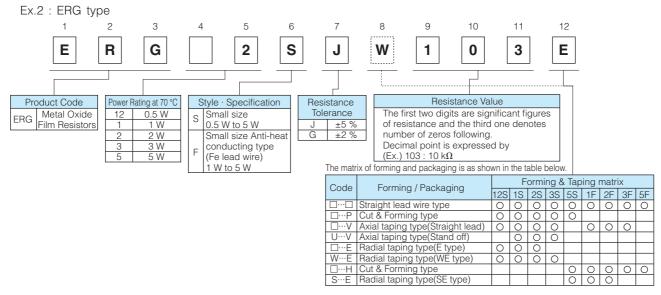
IEC 60115-2, IEC 60115-4, JIS C 5201-4, EIAJ RC-2138

RoHS compliant

Explanation of Part Numbers



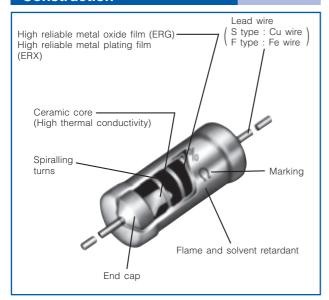
The above example 1 shows a small metal film resistor, 2 W power rating, resistance value of 1.0 Ω , tolerance ±5 %, and package of radial taping



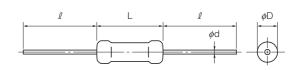
The above example 2 shows a small metal oxide film resistor, 2 W power rating, resistance value of 10 k Ω , tolerance ± 5 %, and package of radial taping

Metal (Oxide) Film Resistors

Construction



Dimensions in mm (not to scale)



Part No.		Dimensio	ons (mm)		Mass (Weight) [g/pc.]	
rait No.	L	φD	l	ø d		
ERG(X)12S	6.35+0.65 -0.35	2.3 ^{+0.5} _{-0.3}	30.0 ^{±3.0}	0.65 ^{±0.05}	0.26	
ERG(X)1S	9.00+1.50	2.8 ^{±0.5}	30.0 ^{±3.0}	0.65 ^{±0.05}	0.33	
ERG(X)1F	9.00-1.00	2.0	30.0	0.80 ^{±0.05}	0.33	
ERG(X)2S ERG(X)2F	12.00+1.50	4.0 ^{±1.0}	30.0 ^{±3.0}	0.80 ^{±0.05}	0.66	
ERG(X)3S ERG(X)3F	15.00 ^{±1.50}	5.5 ^{±1.0}	38.0 ^{±3.0}	0.80 ^{±0.05}	1.47	
ERG(X)5S ERG(X)5F	24.00 ^{±1.50}	8.0 ^{±1.0}	38.0 ^{±3.0}	0.80 ^{±0.05}	3.54	

Ratings

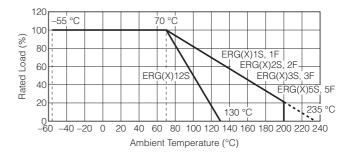
Part No.	Power Rating at 70 °C (W)	Limiting Element Voltage ⁽¹⁾	Maximum Overload Voltage ⁽²⁾	Overload Voltage ⁽²⁾ Voltage ⁽³⁾		Res. Tol. (%) ⁽⁴⁾	Resistance Range $(\Omega)^{(5)}$		T.C.R. (×10 ⁻⁶ /°C)	Standard Resistance Value	
	(v v)	(V)	(V)	(V)	(VAC)		min. ⁽⁶⁾	max.			
ERG(X)12S	0.5	300	600	600	350	G (±2)	1	22 k	±350	E24	
L110(X)120	0.5	300	000	000	000 330		0.2	47 k	±330	L24	
ERG(X)1S	1	350	600	600	350	G (±2)	1	68 k	±350	E24	
ERG(X)1F	ľ	330	000	000	330	J (±5)	0.2	100 k	±330	L24	
ERG(X)2S	2	350	700	1000	600	G (±2)	1	100 k	±350	E24	
ERG(X)2F		330	700	1000	000	J (±5)	0.22	100 k	±330	L24	
ERG(X)3S	3	350	700	1000	1000	G (±2)	1	100 k	±300	E24	
ERG(X)3F		330	700	1000	1000 1000		±5) 0.22 100 k ±300		±300	L24	
ERG(X)5S	5	500	1000	1500	1000	G (±2)	1	100 k	±200	E24	
ERG(X)5F		300	1000	1300	500 1000		J (±5) 0.33 10		100 k	±200	

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating×Resistance Value or Limiting Element Voltage listed above whichever less.
- (2) Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5×Power Rating or max. Overload Voltage listed above whichever less.
- (3) Intermittent Overload Test Voltage (IOTV) shall be determined from IOTV=4.0×Power Rating or max. Intermittent Overload Voltage listed above whichever less.
- (4) Resistance tolerance is of use besides range listed, please inquire.
- (5) Resistance Range Type ERG : \geq 10 Ω Type ERX : \leq 9.1 Ω
- (6) As for the low resistance value range, "Z" is given to the part number. (Refer to the explanation of part numbers.)
- * Z type is non standard resistance values

Code	Part No.	Res.Tol.	Res. Value Range	Code	Part No.	Res.Tol.	Res. Value Range
	12S	±2 %	0.1 to 0.91 Ω		2S	±2 %	0.1 to 0.91 Ω
7	123	±5 % 0.1 to 0.18 Ω		7	2F	±5 %	0.1 to 0.2 Ω
_	1S	±2 %	0.1 to 0.91 Ω	_	3S	±2 %	0.1 to 0.91 Ω
	1F	±5 %	0.1 to 0.18 Ω		3F	±5 %	0.1 to 0.2 Ω

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



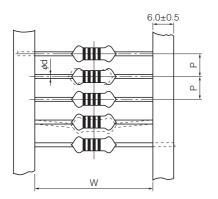
Metal (Oxide) Film Resistors Packaging Methods

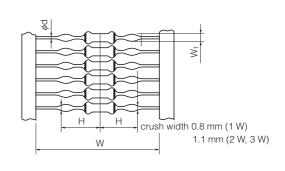
Taped & Box

 $ERG(X)\square\square S\square\square\square\square V$

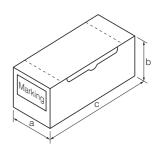
Stand-off Taped & Box

 $ERG(X)\square\square S\square U\square\square\square V$



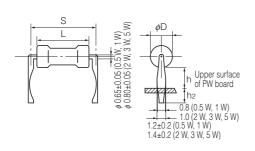


Part Number	Standard Quantity	Taping (mm)							Box (mm)		
	(pcs./box)	Р	50×P	W	Н	W ₁	ø d	а	b	С	
ERG(X) 12SDDDDV	2,000	5.0 ^{±0.3}	250 ^{±2}	52.0 ^{±1.5}	_	_	0.65 ^{±0.05}	85	80	255	
ERG(X) 1SDDDDV	0.000	0.000	5.0 ^{±0.3}	250 ^{±2}	52.0 ^{±1.5}	_	_	0.65 ^{±0.05}	٥٢	00	255
ERG(X) 1S□U□□□V	2,000	5.0	250	52.0	12.0-2.0	1.20+0.15	0.00	85	80	255	
ERG(X) 2S□□□□□V	1.000	5.0 ^{±0.3}	250 ^{±2}	52.0 ^{±1.5}	_	_	0.80 ^{±0.05}	0.5	00	055	
ERG(X) 2S□U□□□V	1,000	5.0	250	52.0	15.5-2.0	1.40+0.15	0.80	85	80	255	
ERG(X) 3S□□□□□V	1.000	10.0 ^{±0.5}	500 ^{±2}	74.0 ^{±2.0}	_	_	0.80 ^{±0.05}	105	100	205	
ERG(X) 3S□U□□□V	1,000	10.0	500	74.0	23.0-2.0	1.4 0.15	0.80	105	100	325	



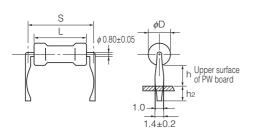
Cut & Formed Type

 $ERG(X)\square\square S\square\square\square\square$ P



Part Number	Standard Quantity	Dimensions (mm)							
	(pcs./box)	L	ϕ D	S	h	h2			
ERG(X)12S□□□□P	1,000	6.35+0.65	2.3 ^{+0.5} _{-0.3}	10.0 ^{±1.5}	4.0 ^{±1.5}	4.0 ^{±1.5}			
ERG(X) 1S□□□P	1,000	9.00+1.50	2.8 ^{±0.5}	12.5 ^{±1.5}	4.0 ^{±1.5}	4.0 ^{±1.5}			
ERG(X) 2S□□□□P	1,000	12.00+1.50	4.0 ^{±1.0}	15.0 ^{±1.5}	6.0 ^{±1.5}	4.0 ^{±1.5}			
ERG(X) 3S□□□P	1,000	15.00 ^{±1.50}	5.5 ^{±1.0}	20.0 ^{±2.0}	6.5 ^{±1.5}	4.0 ^{±1.5}			
ERG(X) 5S□□□□P	500	24.00 ^{±1.50}	8.0 ^{±1.0}	30.0 ^{±2.0}	7.5 ^{±1.5}	4.0 ^{±1.5}			

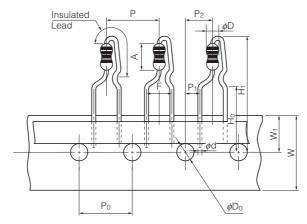
$ERG(X)\Box F\Box\Box\Box\Box H$



Part Number	Standard Quantity	Dimensions (mm)						
	(pcs./box)	L	φD	S	h	h ₂		
ERG(X)1F□□□□H	1,000	9.0+1.5	2.8 ^{±0.5}	12.5 ^{±1.5}	8 ^{±2}	4.0 ^{±1.5}		
ERG(X)2F□□□□H	1,000	12.0+1.5	4.0 ^{±1.0}	15.0 ^{±1.5}	6 ^{±2}	5.0 ^{±1.5}		
ERG(X)3F□□□□H	1,000	15.0 ^{±1.5}	5.5 ^{±1.0}	20.0 ^{±2.0}	10 ^{±2}	5.0 ^{±1.5}		
ERG(X)5F□□□□H	500	24.0 ^{±1.5}	8.0 ^{±1.0}	30.0 ^{±2.0}	10 ^{±2}	5.0 ^{±1.5}		

For Panasert Automatic Insertion Machine Radial Taped & Box

 $ERG(X)\square\square S\square\square\square E$ (12S, 1S, 2S)



Di	imensions (mm)	Di	mensions (mm)	Dimensions (mm)		Dimensions (mm)			Dimensions (mm)			
Р	12.7±1.0	W	18.0±0.5		12S	32 max.		12S	6.35+0.65		12S	2.3+0.5
P ₀	12.7±0.3	W ₁	9.0±0.5	H1	1S	32 max.	А	1S	9.0+1.5	φD	1S	2.8±0.5
P ₁	3.85±0.70				2S	38 max.		2S	12.0+1.5		2S	4.0±1.0
P ₂	6.35±1.00			H∘	16	6.0±0.5	ø d	0.6	5±0.05			
F	5.0±0.8			φDο	4	.0±0.2						

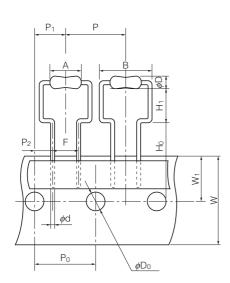
Radial Tape Package Specifications



Part Number	Dim	ensions (Standard Quantity	
T dit i vainiboi	а	b	С	(pcs./box)
ERG(X) 12S□□□□E	46	130	335	2,000
ERG(X) 1S□□□□E	46	130	335	2,000
ERG(X) 2S□□□□E	49	100	335	1,000

For Panasert Automatic Insertion Machine Radial Taped & Box

ERG(X)□□S□W□□□E (12S, 1S, 2S, 3S)



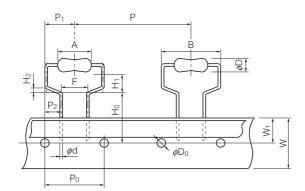
	Dimensions (mm)		Dimensions ((mm)
Р	12S	12.7±1.0	φD ₀	12S, 1S, 2S, 3S	4.0±0.2
Г	1S, 2S, 3S	30.0±1.0		12S	6.35+0.65
P0	12S	12.7±0.3	,	1S	9.0+1.5
P0	1S, 2S, 3S	15.0±0.3	A	2S	12.0+1.5
P ₁	12S	6.35±1.00		3S	15.0±1.5
F1	1S, 2S, 3S	7.5±1.0		12S	11.2 max.
P2	12S	3.85±0.70	В	1S	14.0 max.
Γ2	1S, 2S, 3S	3.75±0.50		2S	17.0 max.
F	12S	5.0±0.5		3S	21.0 max.
Г	1S, 2S, 3S	7.5±0.8		12S	2.3 ^{+0.5} _{-0.3}
W	12S, 1S, 2S, 3S	18.0±0.5	φD	1S	2.8±0.5
W ₁	12S, 1S, 2S, 3S	9.0±0.5	Ψυ	2S	4.0±1.0
	12S	16.0±0.5		3S	5.5±1.0
Hο	1S, 2S	18.0±1.0	φd	12S	φ0.65±0.05
	3S	19.0±1.0	Ψα	1S, 2S, 3S	φ0.80±0.05
	12S	6.5+0.6			
Нı	1S, 2S	6.5+1.0			
	3S	8.0+1.0			



Metal (Oxide) Film Resistors Packaging Methods

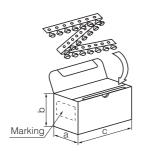
For Panasert Automatic Insertion Machine Radial Taped & Box

ERG(X)□F□S□□□E (1F, 2F, 3F)



	Dimensions	s (mm)		Dimensions	s (mm)		
Р	30	0.0±1.0	H ₂	1.	0±0.3		
P ₀	15	5.0±0.3	φ D₀	4	.0±0.2		
P ₁	7	.5±1.0		1F	9.0+1.5		
P ₂	3.7	'5±0.50	А	2F	12.0+1.5		
F	7	.5±0.8		3F	15.0±1.5		
W	18	3.0±0.5		1F	14 max.		
W ₁	9	.0±0.5	В	2F	17 max.		
H∘	1	6.0 ^{+1.0}		3F	21 max.		
	1F	7.0+1.0		1F	2.8±0.5		
H ₁	2F 8.0 ^{+1.0}		ϕ D	2F	4.0±1.0		
	3F 9.0 ^{+1.0}			3F	5.5±1.0		
			<i>ø</i> d	0.8	80±0.05		

Radial Tape Package Specifications

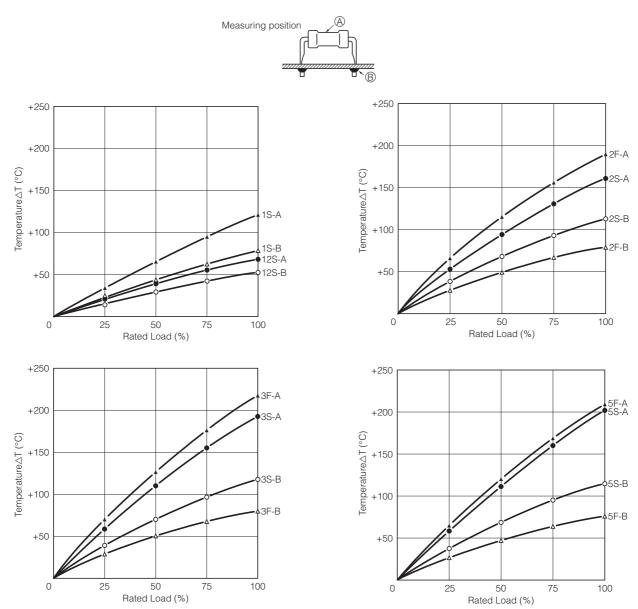


Part No.	Dim	ensions (mm)	Standard Quantity	
	а	b	С	(pcs./box)	
ERG(X)12S□W□□□E	46	145	325	2,000	
ERG(X) 1S□W□□□E	49	49 150	317	1.000	
ERG(X) 1F□ S□□□E	49	130	317	1,000	
ERG(X) 2S□W□□□E	49	450	317	500	
ERG(X) 2F□ S□□□E	49	150	317	500	
ERG(X) 3F□ S□□□E	49	190	315	500	



Hot-spot Temperature (for Reference)

The temperature of the resistor body increases with the curve below. A touching vinyl wire may cause damages to resistor element. Do not place vinyl wires around resistors and be sure to consider where the resistors will be placed.



The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

1. Transient voltage

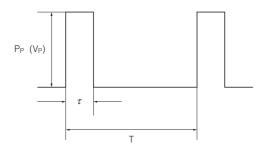
- If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of Metal(Oxide) Film Resistors (hereafter called the resistors) mounted on your product rather than only depending on the calculated power limit or steady-state conditions to complete the design or decide to use the resistors.
- 2. The resistors are covered with a special coating. Do not apply shock or vibration to them, or pinch them with long-nose pliers. Otherwise, the resistors may be damaged.
- 3. Do not apply excessive tension to the lead-connected sections. When bending the lead wire, do not apply excessive stress to the resistors and provide the wire with a natural curvature.
- 4. Do not brush the resistors during or after the cleaning process, which may be conducted after soldering. Otherwise, the coating film may be damaged.



Metal (Oxide) Film Resistors

(Data for Reference)

Pulse Characteristics (Usual)



: Pulse limit power (W) : Pulse limit voltage (V) : Pulse continuous time (s)

Т : Period (s)

 V_R : Rated voltage (V) Ρ : Rated power (W) : Resistance value (Ω) V_{p max.}: Max. pulse limit voltage (V)

Withstand pulse limit power is calculated by the next method.

 $P_P = K \cdot P \cdot T / \tau$ $V_P = \sqrt{K \cdot P \cdot R \cdot T / \tau}$

Reference to the right about a fixed number of $V_{P\ max.}$

• T>1(s) \rightarrow T=1(s)

 $T/\tau > 100 \rightarrow T/\tau = 100$ $P_P < P \rightarrow P$ stands for P_P $(V_P < V_R \rightarrow V_R)$ stands for V_P)

Added voltage≤V_{p max.}

P_P or V_P is referent value

Conditions: Pulse added time=1000 h

Resistance change=±5 %

Room temperature

Part No.	К	Vpmax. (V)
ERG(X) 12S	0.5	600
ERG(X) 1S	0.5	600
ERG(X) 2S	0.5	700
ERG(X) 3S	0.5	700
ERG(X) 5S	0.5	1000

Anti-Pulse Power Resistors

Anti-Pulse Power Resistors

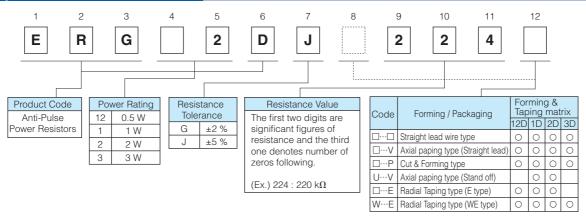
Type: **ERGD** (0.5 W, 1 W, 2 W, 3 W)



Features

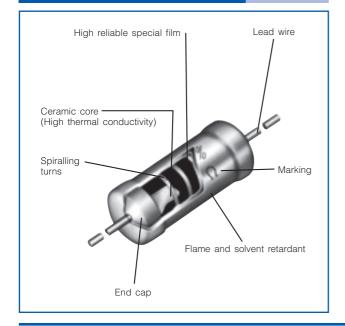
- Miniaturized
- Non-flammable
- Anti-Pulse Characteristic
- Automatic Insertion
- RoHS compliant

Explanation of Part Numbers

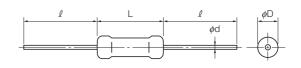


The above example shows an anti-pulse resistor, 2 W power rating, resistance value of 220 k ohms, tolerance ±5 %, and package of standard bulk packing.

Construction



Dimensions in mm (not to scale)



Part No.		Dimension	ons (mm)		Mass (Weight)
	L	ϕ D	l	ø d	[g/pc.]
ERG12D	6.35+0.65 -0.35	2.3+0.5	30.0 ^{±3.0}	0.65 ^{±0.05}	0.26
ERG1D	9.00+1.50	2.8 ^{±0.5}	30.0 ^{±3.0}	0.65 ^{±0.05}	0.33
ERG2D	12.00+1.50	4.0 ^{±1.0}	30.0 ^{±3.0}	0.80 ^{±0.05}	0.66
ERG3D	15.00 ^{±1.50}	5.5 ^{±1.0}	38.0 ^{±3.0}	0.80 ^{±0.05}	1.47



Anti-Pulse Power Resistors

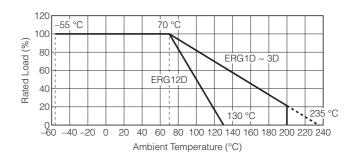
Ratings

Part No.	Power Rating at 70 °C (W)	Limiting Element Voltage ⁽¹⁾	Maximum Overload Voltage ⁽²⁾	0	Dielectric Withstanding Voltage	Res. Tol. (%)		tance $\in (\Omega)^{^{(4)}}$	Standard Resistance Value
	((())	(V)	(V)	(V)	(VAC)		min.	max.	
ERG12D	0.5	400	800	800	500	J (±5) G (±2)	51 k	240 k	E24
ERG1D	1	500	1000	1000	500	J (±5) G (±2)	110 k	330 k	E24
ERG2D	2	500	1000	1000	700	J (±5) G (±2)	110 k	510 k	E24
ERG3D	3	500	1000	1000	700	J (±5) G (±2)	110 k	750 k	E24

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating×Resistance Value or Limiting Element Voltage listed above whichever less.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



As for Packaging Methods and / or cut formed leads,

Please see Metal (Oxide) Film Resistors Packaging Methods

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

1. Transient voltage

- If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of Anti-Pulse Power Resistors (hereafter called the resistors) mounted on your product rather than only depending on the calculated power limit or steady-state conditions to complete the design or decide to use the resistors.
- 2. The resistors are covered with a special coating. Do not apply shock or vibration to them, or pinch them with long-nose pliers. Otherwise, the resistors may be damaged.
- 3. Do not apply excessive tension to the lead-connected sections. When bending the lead wire, do not apply excessive stress to the resistors and provide the wire with a natural curvature.
- 4. Do not brush the resistors during or after the cleaning process, which may be conducted after soldering. Otherwise, the coating film may be damaged.

⁽²⁾ Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5×Power Rating or max. Overload Voltage listed above whichever less.

⁽³⁾ Intermittent Overload Test Voltage (IOTV) shall be determined from IOTV=4.0×Power Rating or max. Intermittent Overload Voltage listed above whichever less.

⁽⁴⁾ Resistance tolerance and resistance range is of use besides range listed, please inquire.

Metal Film Resistors

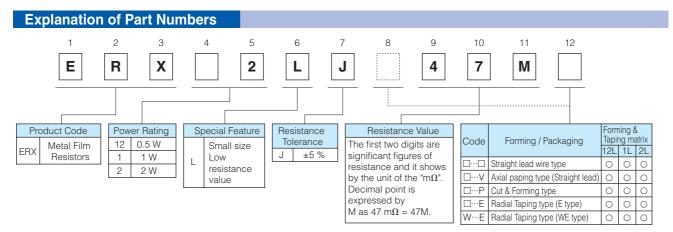
Type: ERXL (Low Resistance Value)

(0.5 W, 1 W, 2 W)



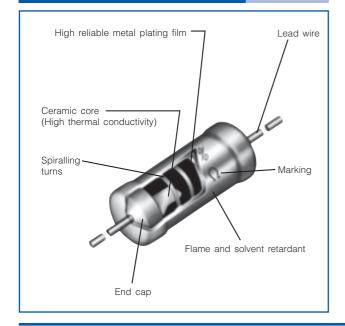
Features

- Miniaturized
- Non-flammable
- Automatic Insertion
- RoHS compliant

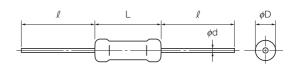


The above example shows a small size and low resistance value metal film resistor, 2 W power rating, resistance value of 47 m ohms, tolerance ±5 %, and package of standard bulk packing

Construction



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)					
	L	φD	l	ø d	(Weight) [g/pc.]		
ERX12L	6.35 ^{+0.65} _{-0.35}	2.3 ^{+0.5} _{-0.3}	30.0 ^{±3.0}	0.65 ^{±0.05}	0.26		
ERX1L	9.00+1.50	2.8 ^{±0.5}	30.0 ^{±3.0}	0.65 ^{±0.05}	0.33		
ERX2L	12.00+1.50	4.0 ^{±1.0}	30.0 ^{±3.0}	0.80 ^{±0.05}	0.66		

Panasonic Metal Film Resistors, Low Resistance Value

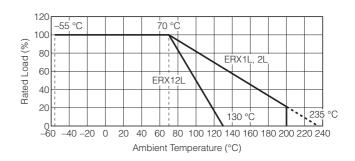
Ratings

Part No.	Power Rating at 70 °C (1)	Dielectric Withstanding Voltage	Res. Tol. (%) (2)		tance $\left(\Omega ight)^{(2)}$	T.C.R. (×10 ⁻⁶ /°C)	Standard Resistance Value
	(W)	(VAC)		min.	max.		
ERX12L	0.5	350	J (±5)	22 m	82 m		E12
ERX1L	1	350	J (±5)	22 m	82 m	22 to 39 m Ω =±1000 47 to 82 m Ω =± 500	E12
ERX2L	2	600	J (±5)	22 m	82 m		E12

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating×Resistance Value.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



■ As for Packaging Methods and / or cut formed leads,

Please see Metal (Oxide) Film Resistors Packaging Methods

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

1. Transient voltage

- If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of Metal Film Resistors (hereafter called the resistors) mounted on your product rather than only depending on the calculated power limit or steady-state conditions to complete the design or decide to use the resistors.
- 2. The resistors are covered with a special coating. Do not apply shock or vibration to them, or pinch them with long-nose pliers. Otherwise, the resistors may be damaged.
- 3. Do not apply excessive tension to the lead-connected sections. When bending the lead wire, do not apply excessive stress to the resistors and provide the wire with a natural curvature.
- 4. Do not brush the resistors during or after the cleaning process, which may be conducted after soldering. Otherwise, the coating film may be damaged.

⁽²⁾ Resistance tolerance and resistance range is of use besides range listed, please inquire.



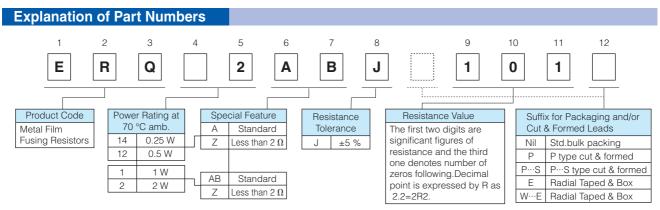
Type: **ERQA ERQZ**

(0.25 W, 0.5 W, 1 W, 2 W coating type)

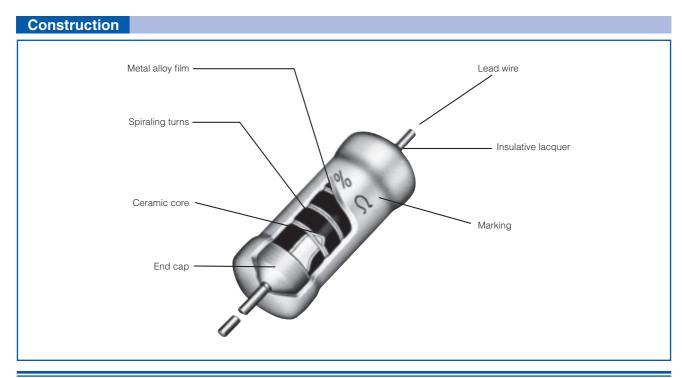


Features

- Accurate fusing
- Small size and lightweight
- Uniform quality, consistent performance and reliability
- Flame retardant, utilizing exclusive silicon insulation material
- Reference Standard FIAJ RC-2125
- RoHS compliant



The above example shows a standard Metal Film Fusing Resistors, 2 W power rating, resistance value of 100 Ω , tolerance of ± 5 %, and package of standard bulk packing.

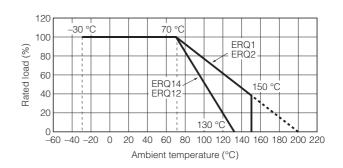


Rating	Ratings											
Part No. Rating Circui	Rating Open		Maximum Overload		Resistance Tolerance	Resistance Range (Ω)		T.C.R.	Standard Resistance	Marking Method	Mass (Weight) [g/pc.]	
	Voltage ⁽¹⁾		standing Tolerance Voltage (%)		min.	max.	(×10 ⁻⁶ /°C)	Values	on Body			
ERQ14Z	0.25	200		AC 350	AC 350 J (± 5)	1.0	1.8	±350	E24	Color	0.24	
ERQ14A	0.23	200			710 000 0 (± 0)	2.0	470	±330		code		
ERQ12Z	0.5	250		AC 350	1 (. E)	1.0	1.8	±350	Eq.4 St	Stamp		
ERQ12A	0.5	250	3 times of rated	AC 330	J (± 5)	2.0	560	±330	E24	Color code	0.32	
ERQ1Z	4	250	voltage ⁽²⁾	A C 600	1 (, E)	1.0	1.8	±350	E24	Ctomp	0.64	
ERQ1AB	ı	250	Voltage	AC 600	AC 600 J (± 5)	J (± 5)	2.0	560	±350	E24	Stamp	0.64
ERQ2Z	2	250		AC 1000) (, 5)	1.0	1.8	±350	E24	04	1 [1	
ERQ2AB		230		AC 1000	AC 1000 J (± 5)		560	±350	⊏24	Stamp	1.54	

Maximum Open Circuit Voltage: Referring to the maximum value of the voltage applied between terminals of the resistor when the resistor is opened in an electric circuit 1000 times power rating or voltage specified above whichever less is regarded as the maximum open circuit voltage.
 Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value

Power Derating Curve

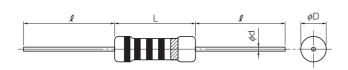
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Performance Specifications

Characteristics	Specifications			Test Methods
Fusing Characteristics	Rated Power 0.25 W 0.5 W 1 W 2 W 0.25 W 0.5 W 1 W 2 W	Res. Value (Ω) - 1 to 1.8		The test potential shall be preadjusted using a dummy resistor and then be subjected to the test specimens. The potential shall be readjusted within two seconds to reach the exact value of specified current. This test shall be made under the conditions at 20 °C and 65 % RH (or at a temperature of 5 °C to 35 °C and 45 to 85 % RH, only when any doubt may not be caused), and the use of stabilized power source is suggested. Fusing time shall be measured as the duration until the circuit current is decreased to a 1/50 the initial test
	0.25 W	10 to 470	Open within	current or less.
	0.5 W 1 W 2 W	10 to 560	30 seconds at 12 times the rated power	

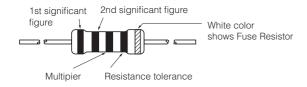
Dimensions in mm (not to scale)



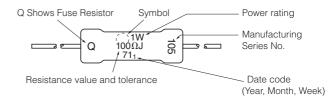
Part No.	Dimensions (mm)						
ran No.	L	ϕ D	l	<i>∲</i> d			
ERQ14	6.3+1.5	2.3 ^{±0.5}	30.0 ^{±3.0}	0.65 ^{±0.05}			
ERQ12	9.0+1.5	2.8 ^{±0.5}	30.0 ^{±3.0}	0.65 ^{±0.05}			
ERQ1	12.0+1.5	4.0 ^{±1.0}	30.0 ^{±3.0}	0.80 ^{±0.05}			
ERQ2	15.0 ^{±1.5}	5.5 ^{±1.0}	38.0 ^{±3.0}	0.80 ^{±0.05}			

Explanation of Marking

Type ERQ14, ERQ12 (0.25 W, 0.5 W)

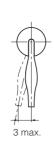


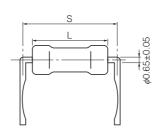
Type ERQ1, ERQ2 (1W, 2W)

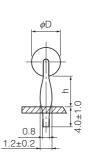


Cut & Formed Type





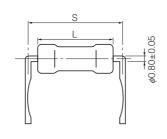


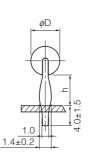


Part No.	Power Rating at 70 °C	Standard Q'ty/Packing	Dimensions (mm)					
Part No.	(W)	(pcs.)	L	ϕ D	S	h		
ERQ14□J□□□P	0.25	2,000	6.3+1.5	2.3 ^{±0.5}	10.0 ^{±1.5}	4.0 ^{±1.5}		
ERQ12□J□□□P	0.5	2,000	9.0+1.5	2.8 ^{±0.5}	12.5 ^{±1.5}	4.0 ^{±1.5}		

ERQ□ABJP□□S ERQ□ZJP□□□S

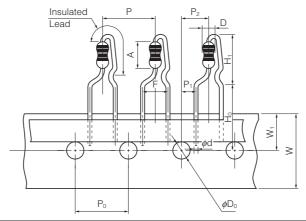






Part No.	Power Rating at 70 °C	Standard Q'ty/Packing	Dimensions (mm)				
	(W)	(pcs.)	L	ϕ D	S	h	
ERQ1DDJPDDS	1	1,000	12.0+1.5	4.0 ^{±1.0}	15.0 ^{±1.5}	6.0 ^{±1.5}	
ERQ2DDJPDDS	2	1,000	15.0 ^{±1.5}	5.5 ^{±1.0}	20.0 ^{±2.0}	6.5 ^{±1.5}	

For Panasert Automatic Insertion Machine Radial Taped & Box



Dimensions (mm)		Dimensions (mm)		Dimensions (mm)		Dimensions (mm)			Dimensions (mm)			
P	12.7±1.0	W	18.0±0.5		14A/14Z	12 max.		14A/14Z	6.35+0.65		14A/14Z	2.3±0.5
P ₀	12.7±0.3	W ₁	9.0±0.5	H₁	12A/12Z	15.5 max.	А	12A/12Z	9.0+1.5	D	12A/12Z	2.8±0.5
P ₁	3.85±0.70				1AB/1Z	19 max.		1AB/1Z	12.0+1.5		1AB/1Z	4.0±1.0
P ₂	6.35±1.00			H₀	16.0±0.5		ø d	0.65=	±0.05			
F	5.0±0.8			ϕ D ₀	4.0±0.2							

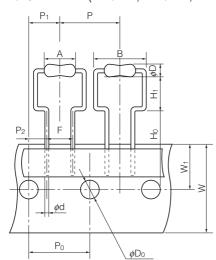
Radial Tape Packaging Methods



Part Number	Dime	ensions (Standard Quantity			
r art r tarrios	а	b c		(pcs./box)		
ERQ14AJ□□□E	46	130	335	2,000 pcs./box		
ERQ14ZJ□□□E	40	130	333			
ERQ12AJ□□E	46	130	335	2,000 pcs./box		
ERQ12ZJ□□□E	40	130	333	2,000 pcs./box		
ERQ1ABJ□□E	49	100	335	1,000 pcs./box		
ERQ1ZJ□□□E	49	100	333	1,000 pcs./box		

For Panasert Automatic Insertion Machine Radial Taped & Box

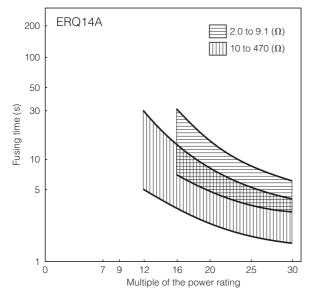
ERQ A/ZJW = (14A/14Z, 12A/12Z, 1AB/1Z)

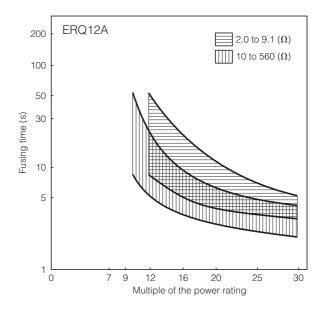


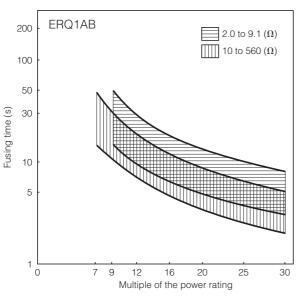
	Dimensions (mm)	Dimensions (mm)			
Р	14A/14Z	12.7±1.0		14A/14Z	6.5+0.6	
Р	12A/12Z, 1AB/1Z	30.0±1.0	H₁	12A/12Z	6.5+1.0	
P ₀	14A/14Z	12.7±0.3		1AB/1Z	6.5+1.0	
Γ0	12A/12Z, 1AB/1Z	15.0±0.3	ϕD_0	4.0±0	.2	
P ₁	14A/14Z	6.35±1.00		14A/14Z	6.35+0.65	
Г 1	12A/12Z, 1AB/1Z	7.5±1.0	Α	12A/12Z	9.0+1.5	
P ₂	14A/14Z	3.85±0.70		1AB/1Z	12.0+1.5	
Γ2	12A/12Z, 1AB/1Z	3.75±0.50		14A/14Z	11.2 max.	
F	14A/14Z	5.0+0.6	В	12A/12Z	14 max.	
Г	12A/12Z, 1AB/1Z	7.5+0.6		1AB/1Z	17 max.	
W	18.0±0	0.5		14A/14Z	2.3+0.5	
W_1	9.0±0	.5	ϕ D	12A/12Z	2.8±0.5	
	14A/14Z	14A/14Z 16.0±0.5		1AB/1Z	4.0±1.0	
H_0	12A/12Z	18.0±1.0	φ _d	14A/14Z	0.65±0.05	
	1AB/1Z	18.0±1.0	γα	12A/12Z, 1AB/1Z	0.80±0.05	

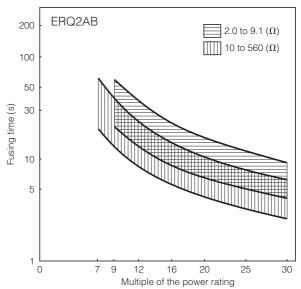
Fusing Characteristics (Constant Voltage Circuit)

This data is for reference only, specifications should be verified in written form with the engineering division.

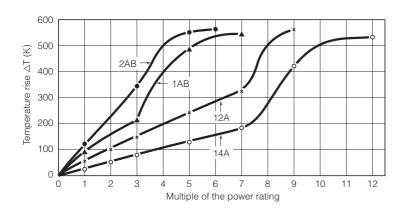


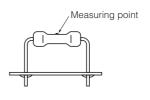






Hot Spot Temperature (for reference)





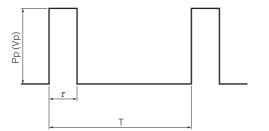
The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- 1. Checking the fusing conditions
 - 1) Fusing characteristics differ depending on the type, shape, and resistance. Check the fusing conditions before selecting the type of Metal Film Fusing Resistors (hereafter called the fusing resistor) to be used.
 - 2) Use the fusing resistors under the maximum open circuit voltage. Otherwise, arcing may occur when a voltage much higher than the rated one is applied in the event of an abnormality in the circuit, or when a high voltage is applied after fusing.
 - 3) Under abnormal conditions of a constant voltage circuit, a current of about 2 or 3 times the initial abnormal current passes through, accelerating the speed at which the fusing resistors blows. When using a constant current circuit, carefully check the conditions because the fusing resistors may not blow in a constant current circuit.
- 2. Checking for pulse voltage, impact voltage, and transient voltage Make sure to evaluate and check the fusing resistors mounted on your product if they are to be mounted on a circuit that generates an impact voltage, or if there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a pulse voltage with a high peak voltage may be applied. Make sure to consult our sales staff before using the fusing resistors under special conditions.
- 3. Conditions of use in a steady state

 Make sure that the load conditions have a sufficient allowance for the power derating curve. The characteristics of
 the fusing resistors are set by using a constant voltage circuit.
- 4. The solvent resistance of the fusing resistors is not assured. If you use a solvent for cleaning after soldering or other processes, make sure to consult our sales staff before use and perform a prior test and evaluation to ensure that the solvent will not affect the reliability of the fusing resistors.

(Data for Reference)

Pulse Characteristics (Usual)



 P_P : Pulse limit power (W) V_P : Pulse limit voltage (V) τ : Pulse continuous time (s)

 $\begin{array}{lll} T & : \mbox{ Period (s)} \\ V_{\mbox{\scriptsize R}} & : \mbox{ Rated voltage (V)} \\ P & : \mbox{ Rated power (W)} \\ R & : \mbox{ Resistance value } (\Omega) \\ V_{\mbox{\tiny pmax.}} & : \mbox{ Max. pulse limit voltage (V)} \end{array}$

Withstand pulse limit power is calculated by the next method.

$$P_{P} = K \cdot P \cdot T/\tau$$

$$V_{P} = \sqrt{K \cdot P \cdot R \cdot T/\tau}$$

Reference to the right about a fixed number of V_{Pmax}.

Part No.	К	Vp max. (V)
ERQ14A	0.6	200
ERQ12A	0.6	250
ERQ1AB	0.6	250
ERQ2AB	0.4	250

- \bullet T>1(s) \rightarrow T=1(s)
- \bullet T/ τ >100 \rightarrow T/ τ =100
- $\begin{array}{l} \bullet \; P_P {<} P \; \to \; P \; \text{ stands for } P_P \\ (V_P {<} V_R \; \to \; V_R \; \text{ stands for } V_P) \end{array}$
- Added voltage≦V_{p max.}
- P_P or V_P is reference value

Conditions: Pulse added time=1000 h, Resistance change=±5 % Room temperature



Standard for Resistance Value, Resistance Tolerance and Color Code

Basis Standard

IEC Publication 60062: Marking codes for resistors and capacitors.

IEC Publication 60063: Preferred number series for resistors and capacitors.

JIS C 5062: Marking codes for resistors and capacitors.

JIS C 5063: Preferred number series for resistors and capacitors.

Resistance Values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance Tolerance (Standard)	Ratio	Remarks				
E6	±20 %	⁶ √10≒1.46					
E12	±10 %	¹² √10≒1.21					
E24	± 5 %	²⁴ √10≒1.10	Please refer to standard resistance values shown on this catalog.				
E48	± 2 %	⁴⁸ √10≒1.05	Shown on this catalog.				
E96	± 1%	⁹⁶ √10≒1.02					

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is identified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 Ω .

The examples of a three digit number

The examples of a four digit number

Resistance Code	Value in ohms	Resistance Code	Value in ohms
R56	0.56	R562	0.562
5R6	5.6	5R62	5.62
100	10	56R2	56.2
271	270	1000	100
102	1 k	2711	2.71 k
273	27 k	1002	10 k
104	100 k	2713	271 k
275	2.7 M	1004	1 M
106	10 M	2715	27.1 M
107	100 M	1006	100 M

Fixed Resistors Appendix

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance Code	Tolerance (%)	Examples				
W B C D F G J K M	±0.05 ±0.1 ±0.25 ±0.5 ±1 ±2 ±5 ±10 ±20	$\begin{array}{c} \text{W1001}: 1000\ \Omega \pm 0.05\ \% \\ \text{B1001}: 1000\ \Omega \pm 0.1\ \% \\ \text{C1001}: 1000\ \Omega \pm 0.25\ \% \\ \text{D1001}: 1000\ \Omega \pm 0.5\ \% \\ \text{F1001}: 1000\ \Omega \pm 1\ \% \\ \text{G1001}: 1000\ \Omega \pm 2\ \% \\ \text{J101}: 100\ \Omega \pm 5\ \% \\ \text{K101}: 100\ \Omega \pm 10\ \% \\ \text{M101}: 100\ \Omega \pm 20\ \% \\ \end{array}$				

Color code indication for the resistance value and the tolerance

Fixed resistors whose resistance value and tolerance are indicated by color code follow the standard below.

Color code

Color	First digit	Second digit	Third digit	Multiplier	Resistance tolerance		
00101	T if St digit	Jecond digit	Trilla digit	ivialtipliel	%	Code	
Black	0	0	0	1			
Brown	1	1	1	10	±1	F	
Red	2	2	2	10 ²	±2	G	
Orange	3	3	3	10 ³	±0.05	W	
Yellow	4	4	4	10 ⁴			
Green	5	5	5	10 ⁵	±0.5	D	
Blue	6	6	6	10 ⁶	±0.25	С	
Violet	7	7	7	10 ⁷	±0.1	В	
Gray	8	8	8				
White	9	9	9				
Gold				10 ⁻¹	±5	J	
Silver				10 ⁻²	±10	K	
None					±20	М	

Indication example

Color code of 5 color bands

When the standard resistance value follows E48 series or 96 series, color code of the resistors are indicated by five color bands. Example below is 154 k Ω .

Example 1

1st Color	2nd Color	3rd Color	4th Color	5th Color	
Brown (1)	Green	Yellow	Orange	Brown	
	(5)	(4)	(1000)	(±1 %)	

Color code of 4 color bands

When the standard resistance value follows E6 series, 12 series or 24 series, color code of the resistors are indicated by four color bands. Example below is 15 k Ω .

Example 2

1st Color	2nd Color	3rd Color	4th Color		
Brown (1)	Green (5)	Orange (1000)	Gold (±5 %)		

Sta	ndarc	l Resi	istanc	e Values										
E6	E12	E24	E48	E96	E6	E12	E24	E48	E96	E6	E12	E24	E48	E96
10	10	10	100	100	22	22	22	215	215	47	47	47	464	464
				102					221					475
			105	105				226	226				487	487
				107					232					499
		11	110	110			0.4	237	237			51	511	511
				113			24		243					523
			115	115				249	249				536	536
	12	12	_	118					255					549
	12	12	121	121				261	261		56	56	562	562
				124		27	27		267					576
			127	127		21	21	274	274				590	590
		13		130					280					604
			133	133				287	287			62	619	619
				137					294					634
			140	140			30	301	301				649	649
				143					309					665
			147	147				316	316	68	68	68	681	681
15	15	15		150	33	33	33		324					698
			154	154				332	332				715	715
		16		158					340					732
			162	162				348	348			75	750	750
				165			36		357					768
			169	169				365	365				787	787
				174					374		82	82		806
	18	18	178	178		39	39	383	383				825	825
				182					392					845
			187	187				402	402				866	866
				191					412					887
			196	196			43	422	422			91	909	909
		20		200					432					931
			205	205				442	442				953	953
				210					453					976

CAUTION AND WARNING

- 1. The electronic components contained in this catalog are designed and produced for use in home electric appliances, office equipment, information equipment,
- communications equipment, and other general purpose electronic devices.

 Before use of any of these components for equipment that requires a high degree of safety, such as medical instruments, aerospace equipment, disaster-prevention equipment, security equipment, vehicles (automobile, train, vessel), please be sure to contact our sales representative.
- 2. When applying one of these components for equipment requiring a high degree of safety, no matter what sort of application it might be, be sure to install a protective circuit or redundancy arrangement to enhance the safety of your equipment. In addition, please carry out the safety test on your own responsibility.
- 3. When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance.
- 4. Technical information contained in this catalog is intended to convey examples of typical performances and/or applications and is not intended to make any warranty with respect to the intellectual property rights or any other related rights of our company or any third parties nor grant any license under such rights.
- 5. In order to export products in this catalog, the exporter may be subject to the export license requirement under the Foreign Exchange and Foreign Trade Law of Japan.

 6. No ozone-depleting substances (ODSs) under the Montreal Protocol are used in the manufacturing processes of Automotive & Industrial Systems Company, Panasonic
- Corporation.

Please contact

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